

Functional Inorganic Materials

Fall 2021

Tuesdays: 14.15 - 16.00
Thursdays: 12.15 - 14.00
Remote Zoom lectures

#	Date	Who	Topic
s	Tue 02.11.	Maarit	Introduction + Materials design
2	Thu 04.11.	Antti	Computational materials design
3	Tue 09.11.	Maarit	Superconductivity: High- T_c superconducting Cu oxides
4	Thu 11.11.	Maarit	Ionic conductivity (Oxygen): Oxygen storage and SOFC
5	Tue 16.11.	Maarit	Ionic conductivity (Lithium): Li-ion battery
6	Thu 18.11.	Antti	Thermal conductivity
7	Tue 23.11.	Antti	Thermoelectricity
8	Thu 25.11.	Maarit	Hybrid materials
9	Tue 30.11.	Maarit	Luminescence and optically active materials
10	Thu 02.12.	Antti	Piezoelectricity
11	Tue 07.12.	Antti	Pyroelectricity and ferroelectricity
12	Thu 09.12.	Antti	Magnetic and multiferroic oxides

LECTURE 1: Materials Design

- **Doping & Substitution**
- **Aliovalent Substitution**
- **Mixed Valency**
- **Vacancies & Interstitials**
- **Electronic & Ionic Conductivity**
- **Oxygen Engineering**
- **Relative Ion Sizes & Tolerance Parameters**

1 H																	2 He
3 Li	4 Be											5 B	6 C	7 N	8 O	9 F	10 Ne
11 Na	12 Mg											13 Al	14 Si	15 P	16 S	17 Cl	18 Ar
19 K	20 Ca	21 Sc	22 Ti	23 V	24 Cr	25 Mn	26 Fe	27 Co	28 Ni	29 Cu	30 Zn	31 Ga	32 Ge	33 As	34 Se	35 Br	36 Kr
37 Rb	38 Sr	39 Y	40 Zr	41 Nb	42 Mo	43 Tc	44 Ru	45 Rh	46 Pd	47 Ag	48 Cd	49 In	50 Sn	51 Sb	52 Te	53 I	54 Xe
55 Cs	56 Ba	57 to 71	72 Hf	73 Ta	74 W	75 Re	76 Os	77 Ir	78 Pt	79 Au	80 Hg	81 Tl	82 Pb	83 Bi	84 Po	85 At	86 Rn
87 Fr	88 Ra	89 to 103	104 Rf	105 Ha	106 Sg	107 Ns	108 Hs	109 Mt									

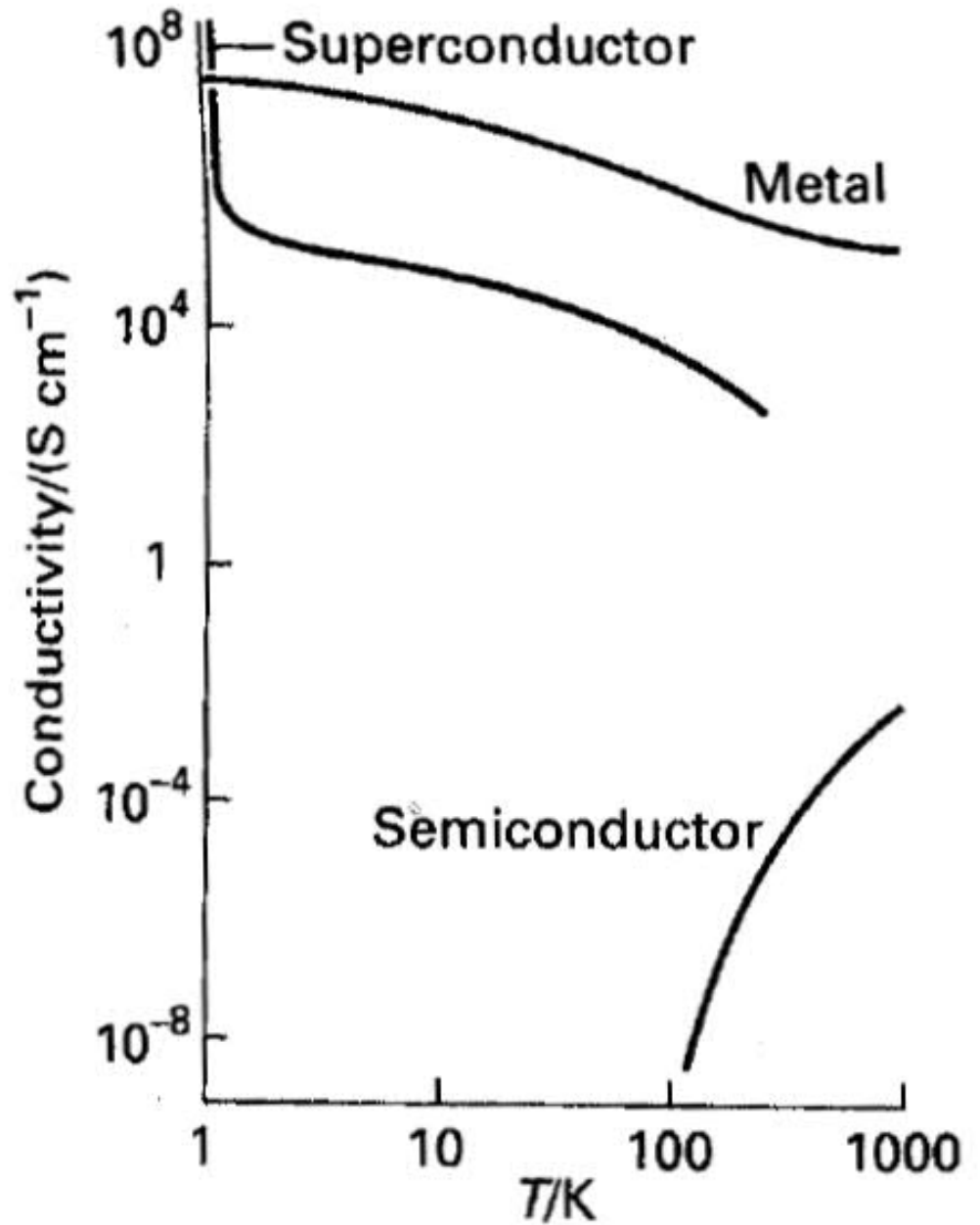
57 La	58 Ce	59 Pr	60 Nd	61 Pm	62 Sm	63 Eu	64 Gd	65 Tb	66 Dy	67 Ho	68 Er	69 Tm	70 Yb	71 Lu
89 Ac	90 Th	91 Pa	92 U	93 Np	94 Pu	95 Am	96 Cm	97 Bk	98 Cf	99 Es	100 Fm	101 Md	102 No	103 Lr

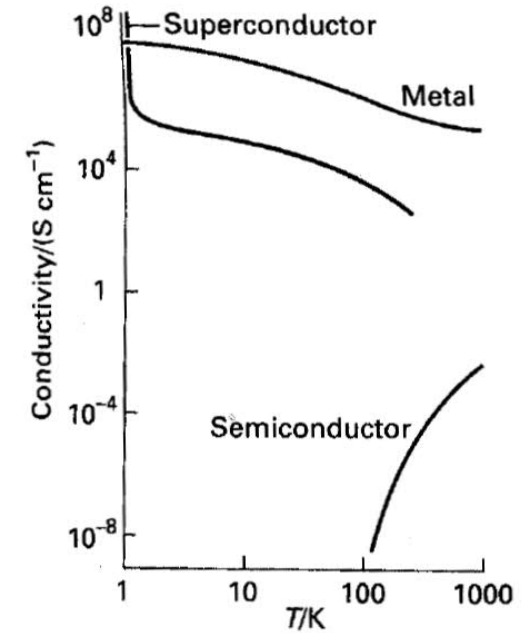
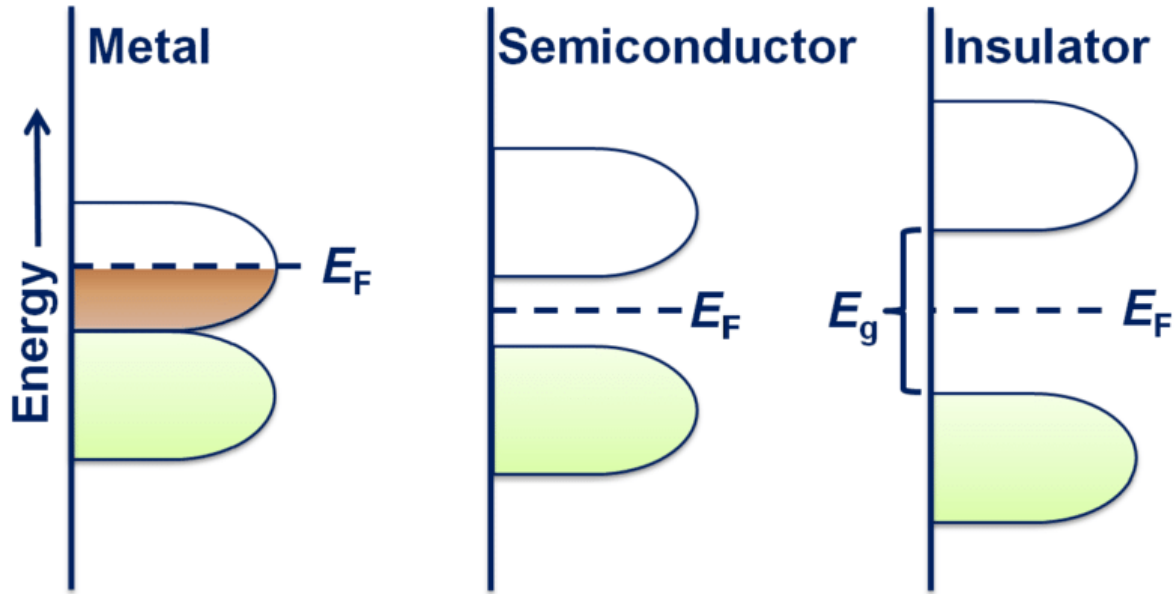
LECTURE EXERCISE 1

1. Assign the type of doped carriers (n-type or p-type) for the following materials (rationalize your answers!): Al-doped Si, $(\text{Zn}_{0.98}\text{Al}_{0.02})\text{O}$, $(\text{Pb}_{0.98}\text{Na}_{0.02})\text{Te}$, $(\text{La}_{0.9}\text{Sr}_{0.1})_2\text{CuO}_4$, $\text{La}_2\text{CuO}_{4.1}$.
2. Calculate the tolerance parameter for the following perovskite compounds (assuming the ionic radius values given below), and judge are they feasible. Also, predict which of them is most easily reduced; most importantly, explain why:
 LaMnO_3 , LaCoO_3 , LaNiO_3 , LaCuO_3 .

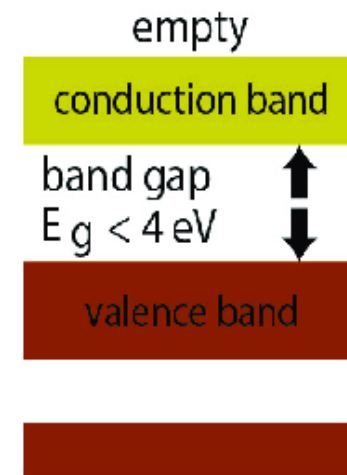
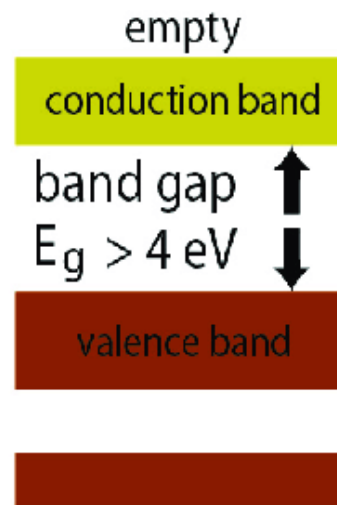
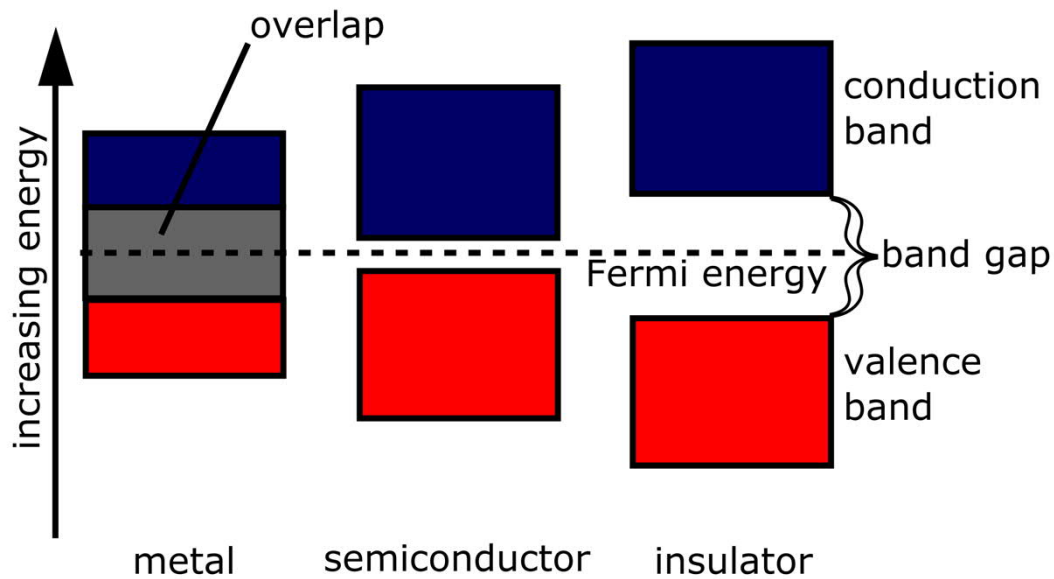
IONIC RADII:	La^{3+}	1.36 Å
	Mn^{3+}	0.65 Å
	Co^{3+}	0.61 Å
	Ni^{3+}	0.60 Å
	Cu^{3+}	0.54 Å
	O^{2-}	1.40 Å

ELECTRICAL CONDUCTIVITY



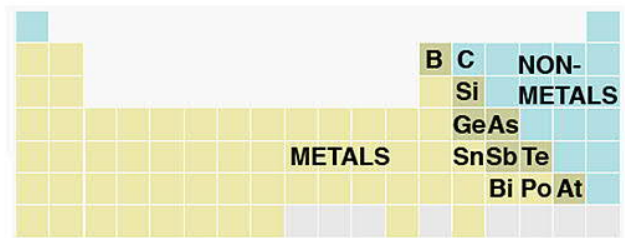
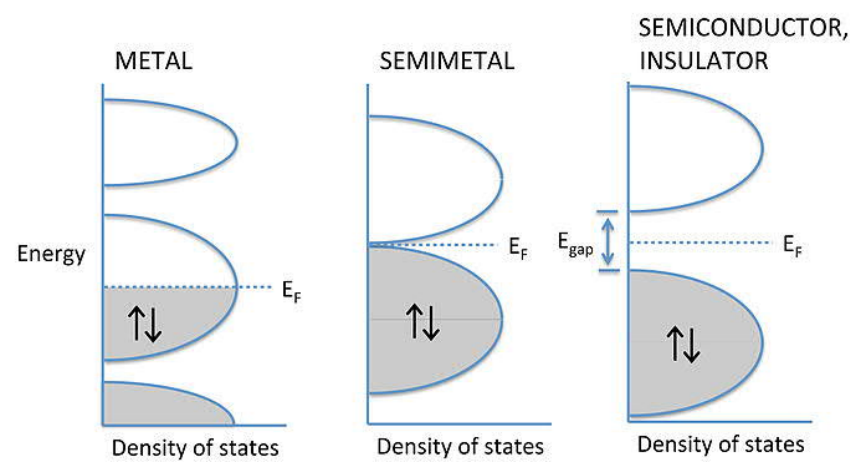


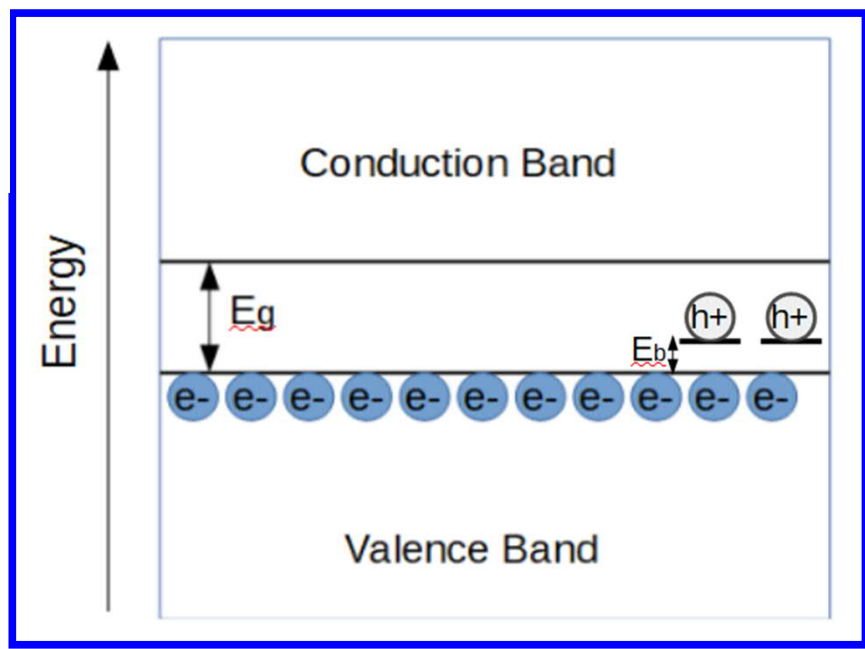
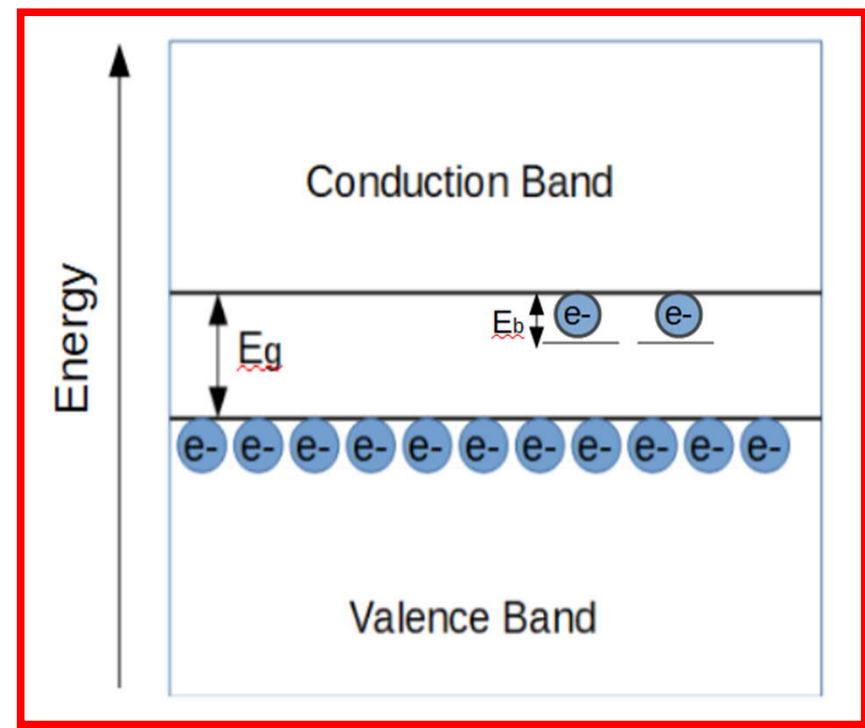
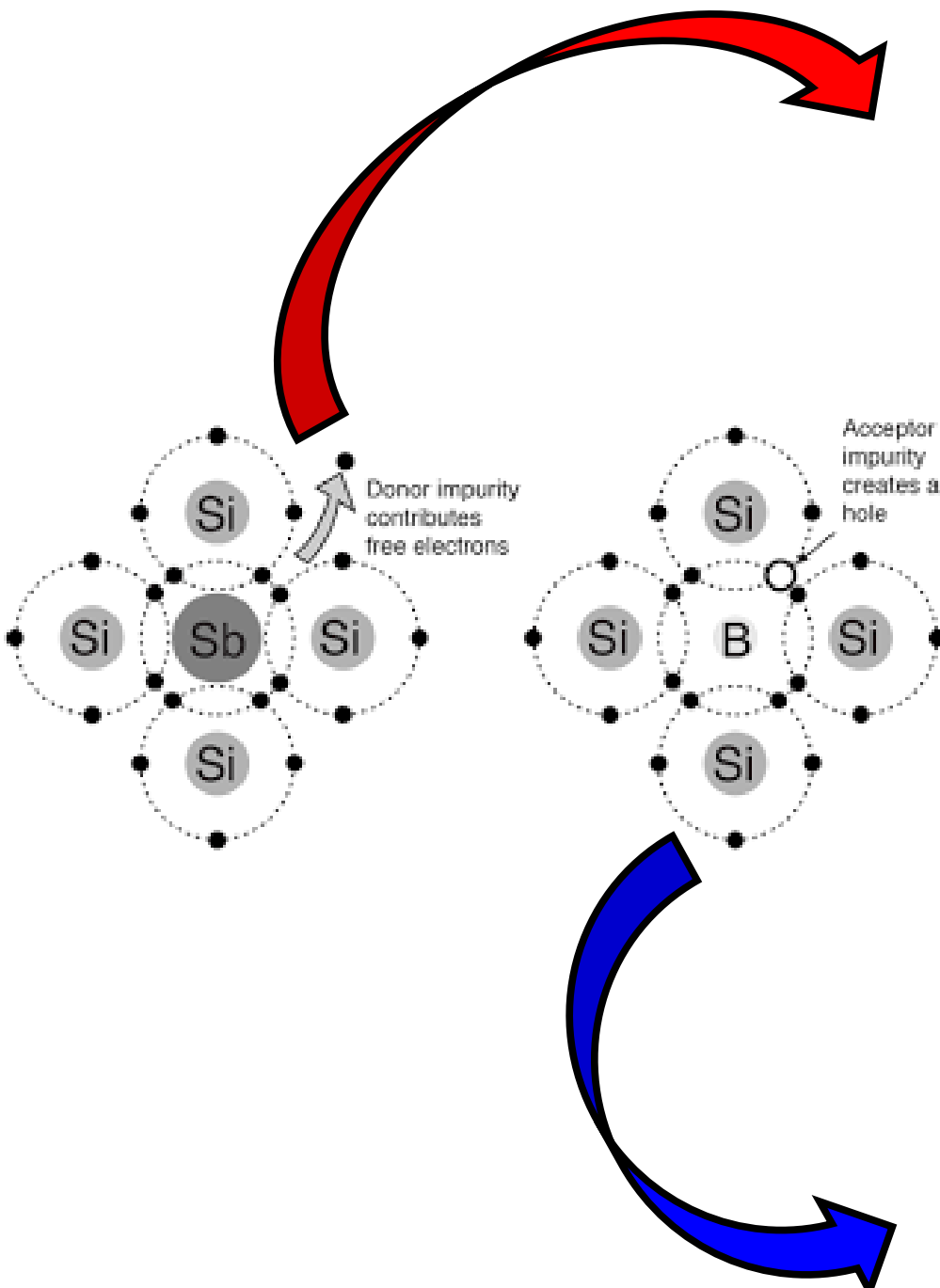
- What are: E_F and E_g ?
- How large is E_g for a semiconductor / an insulator ?
- Can you explain the different temperature dependencies of electrical conductivity for metals and semiconductors ?



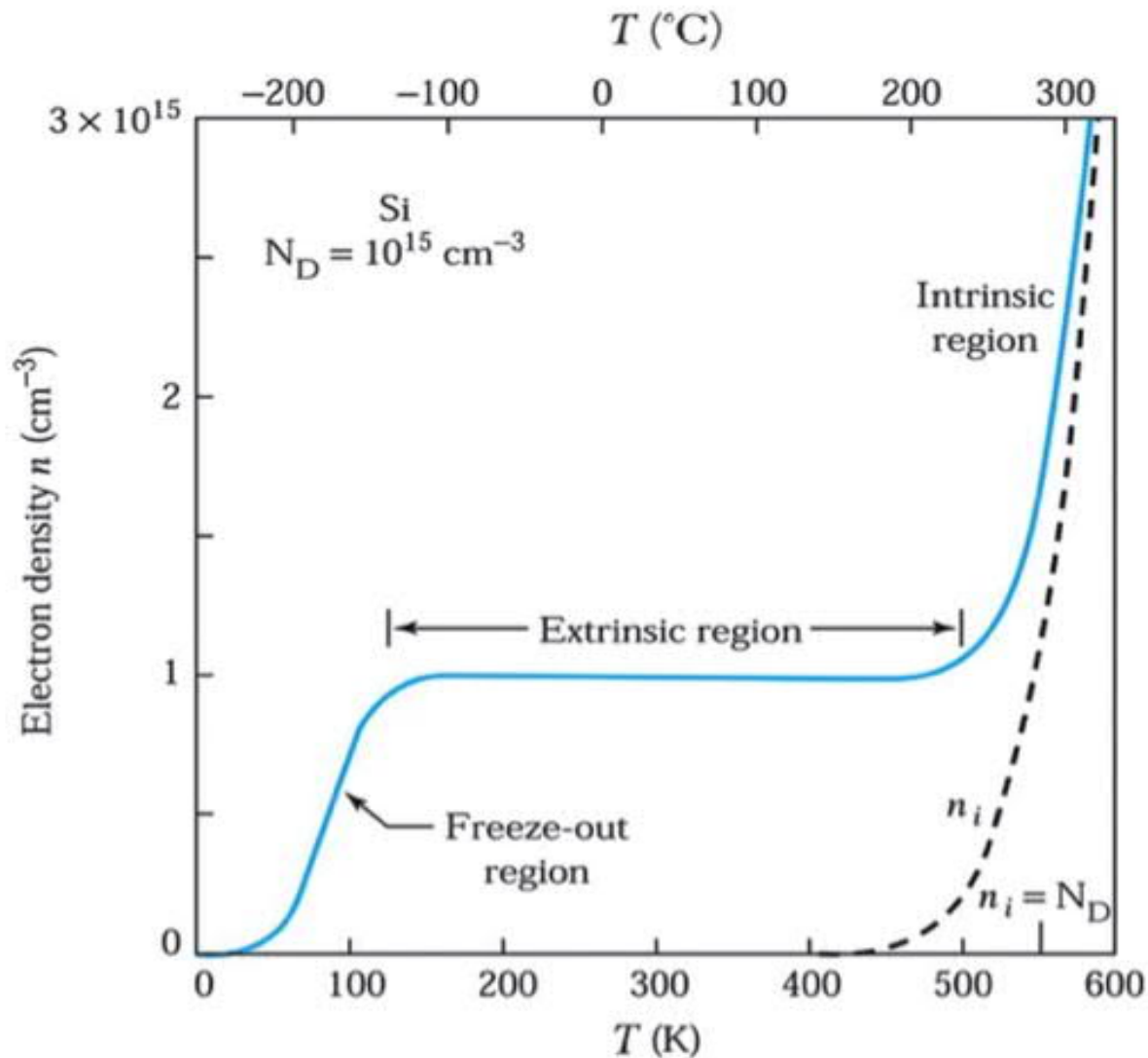
Insulator

Semiconductor

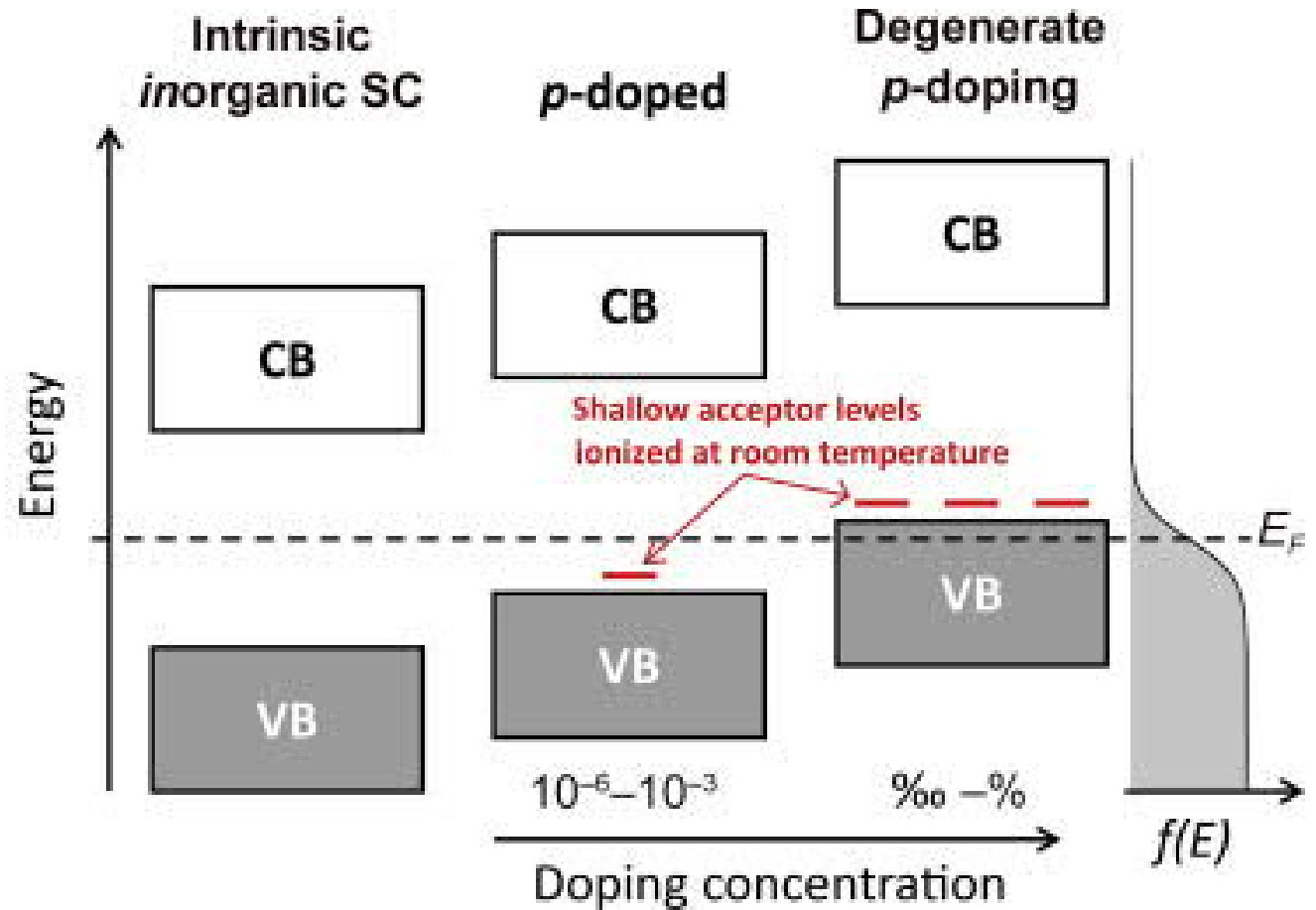
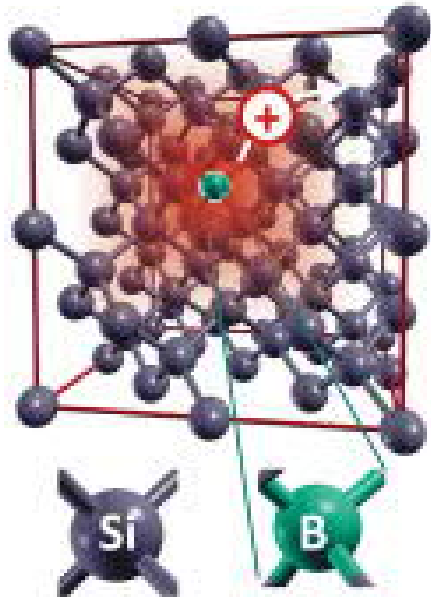




If density of donor atoms is 10^{15} atoms / cm^3 and intrinsic carrier density in Si is given by a curve that was given by Fig 1.18. Regenerate the following figure for temperatures higher than 180 K.



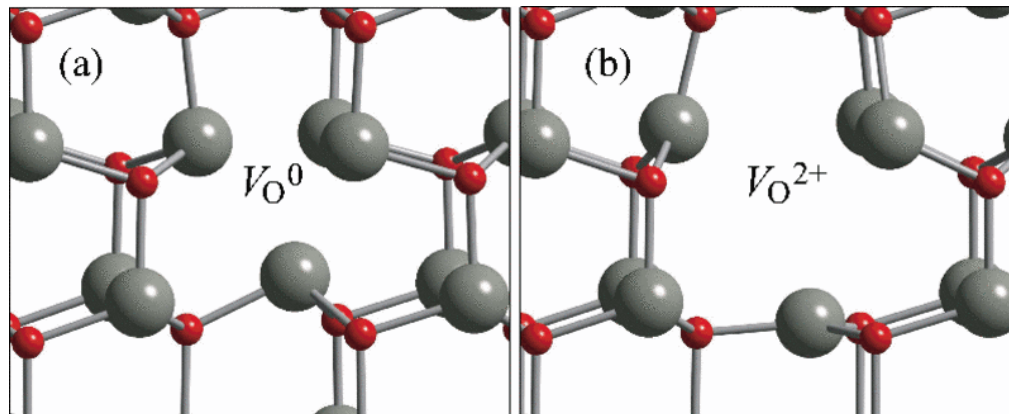
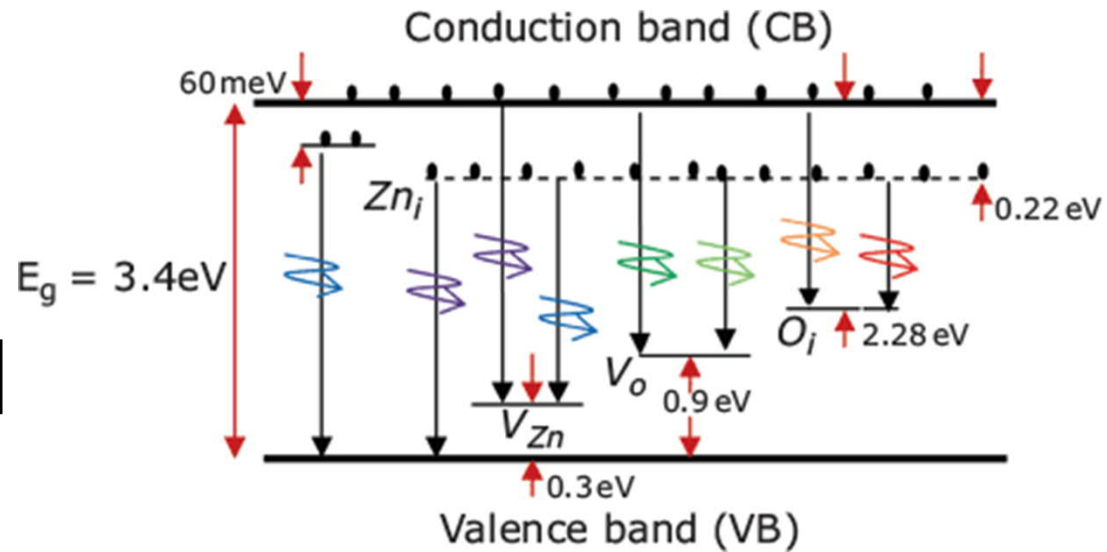
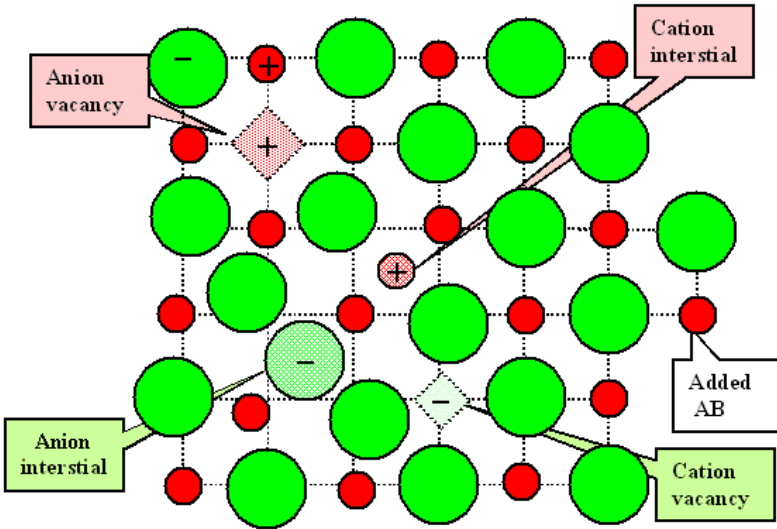
P-doping Si with B



What is the dopant concentration ? !

Simple metal oxide semiconductor: ZnO

- Intrinsically n-type
- What kind of native defects ?



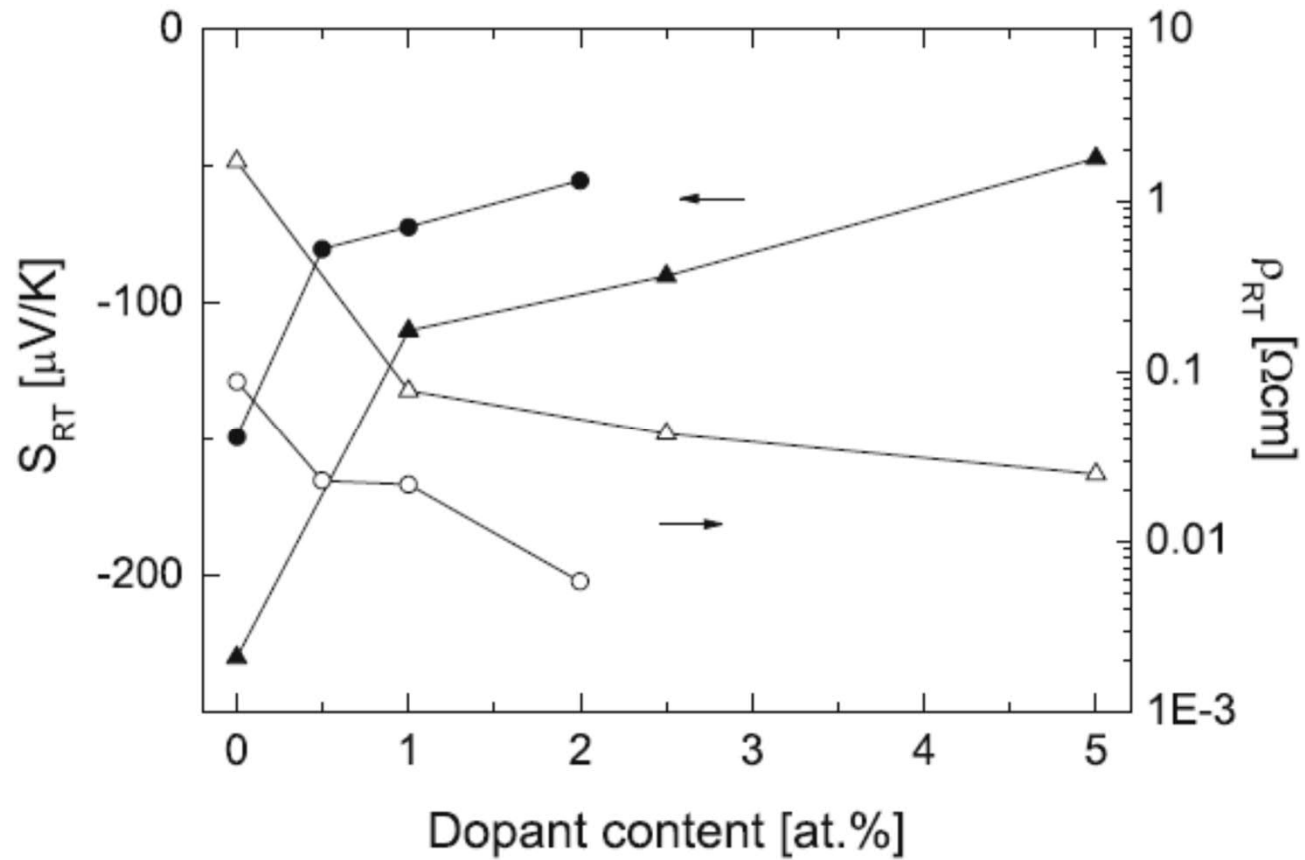
Elements used for doping ALD ZnO

The periodic table below highlights the elements used for doping ALD ZnO in red boxes. These elements are: H, Li, Mg, B, C, N, O, F, Al, Si, P, S, Cl, Ti, V, Mn, Fe, Co, Ni, Ga, Ge, As, Se, Br, Kr, In, Sn, Sb, Te, I, Xe, Hf, Ta, W, Re, Os, Ir, Pt, Au, Hg, Tl, Pb, Bi, Po, At, Rn, Fr, Ra, Rf, Db, Sg, Bh, Hs, Mt, Ds, Rg, Cn, Nh, Fl, Mc, Lv, Ts, Og, La, Ce, Pr, Nd, Pm, Sm, Eu, Gd, Tb, Dy, Ho, Er, Tm, Yb, Lu, Ac, Th, Pa, U, Np, Pu, Am, Cm, Bk, Cf, Es, Fm, Md, No, and Lr.

1	2											10	11	12	13	14	15	16	17	18															
1	H	2	Li	3	Be											10	B	11	C	12	N	13	O	14	F	15	Ne								
3	Na	4	Mg	5	Al	6	Si	7	P	8	S	9	Cl	10	Ar																				
19	K	20	Ca	21	Sc	22	Ti	23	V	24	Cr	25	Mn	26	Fe	27	Co	28	Ni	29	Cu	30	Zn	31	Ga	32	Ge	33	As	34	Se	35	Br	36	Kr
37	Rb	38	Sr	39	Y	40	Zr	41	Nb	42	Mo	43	Tc	44	Ru	45	Rh	46	Pd	47	Ag	48	Cd	49	In	50	Sn	51	Sb	52	Te	53	I	54	Xe
55	Cs	56	Ba	57-71	72	Hf	73	Ta	74	W	75	Re	76	Os	77	Ir	78	Pt	79	Au	80	Hg	81	Tl	82	Pb	83	Bi	84	Po	85	At	86	Rn	
87	Fr	88	Ra	89-103	104	Rf	105	Db	106	Sg	107	Bh	108	Hs	109	Mt	110	Ds	111	Rg	112	Cn	113	Nh	114	Fl	115	Mc	116	Lv	117	Ts	118	Og	
72	La	73	Ce	74	Pr	75	Nd	76	Pm	77	Sm	78	Eu	79	Gd	80	Tb	81	Dy	82	Ho	83	Er	84	Tm	85	Yb	86	Lu						
90	Ac	91	Th	92	Pa	93	U	94	Np	95	Pu	96	Am	97	Cm	98	Bk	99	Cf	100	Es	101	Fm	102	Md	103	No	104	Lr						

Zhengning Gao *and* Parag Banerjee, Review Article: Atomic layer deposition of doped ZnO films, *Journal of Vacuum Science & Technology A* **37**, 050802 (2019); <https://doi.org/10.1116/1.5112777>

What is the substitution level ?



T. Tynell, R. Okazaki, I. Terasaki, H. Yamauchi & M. Karppinen, Electron doping of ALD-grown ZnO thin films through Al and P substitutions, *Journal of Materials Science* **48**, 2806 (2013).

PEROVSKITE STRUCTURE

General formula: $ABO_{3-\delta}$

A: large cation

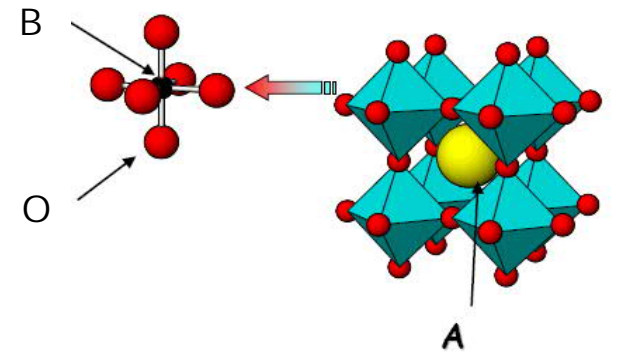
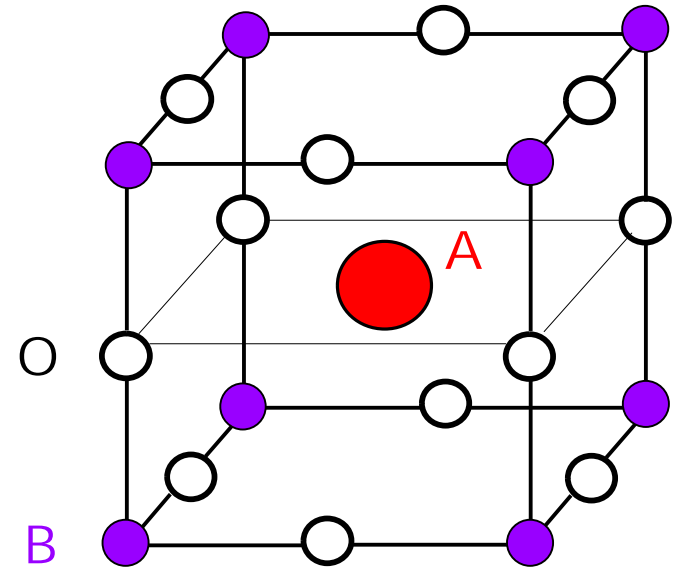
B: small cation (transition metal)

O: oxygen (sometimes halogen)

$V(A) + V(B) = 6$

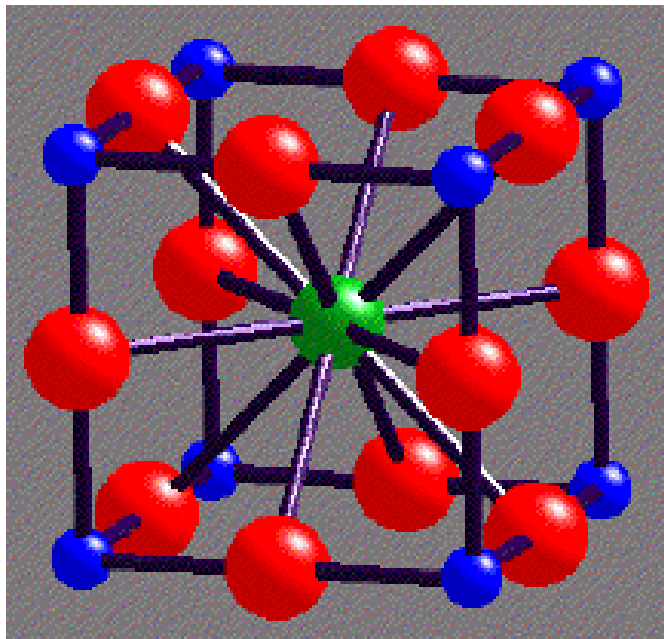
e.g. $La^{III}Sc^{III}O_3$, $Sr^{II}Ti^{IV}O_3$, $Na^{I}Nb^{V}O_3$

$CN(A)=12$, $CN(B)=6$, $CN(O)=6$

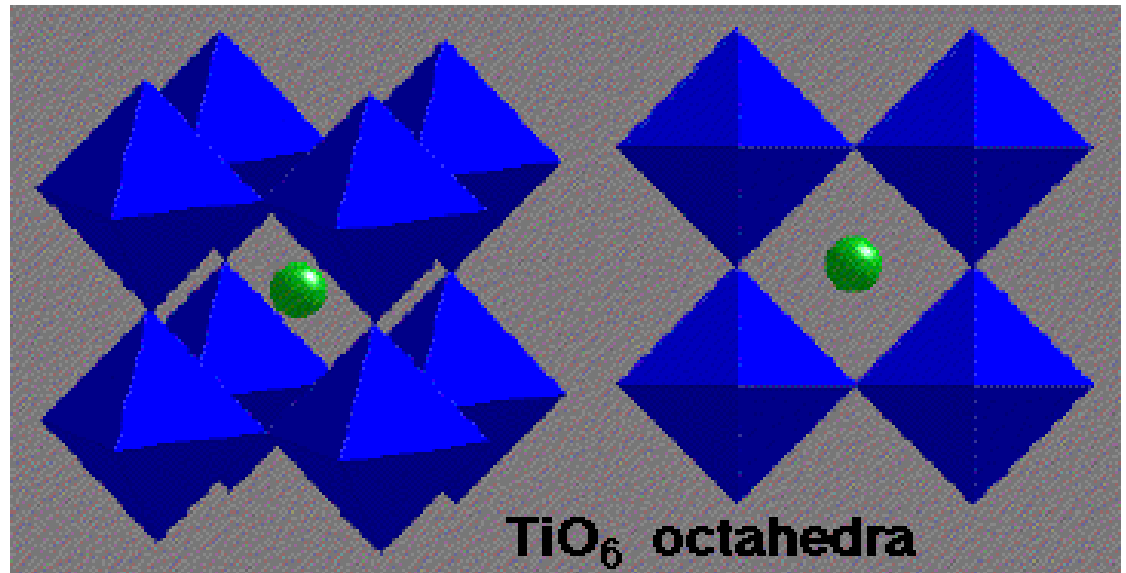


Mineral Perovskite: $CaTiO_3$

- Named after Russian mineralogist, Count Lev Aleksevich von Perovski
- Discovered by Gustav Rose in 1839 from samples found in Ural Mountains

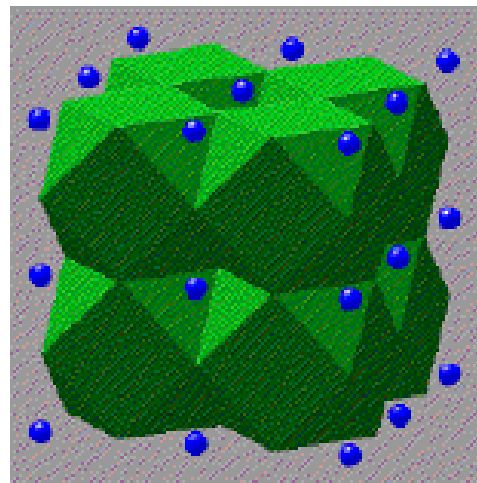


A-Cell

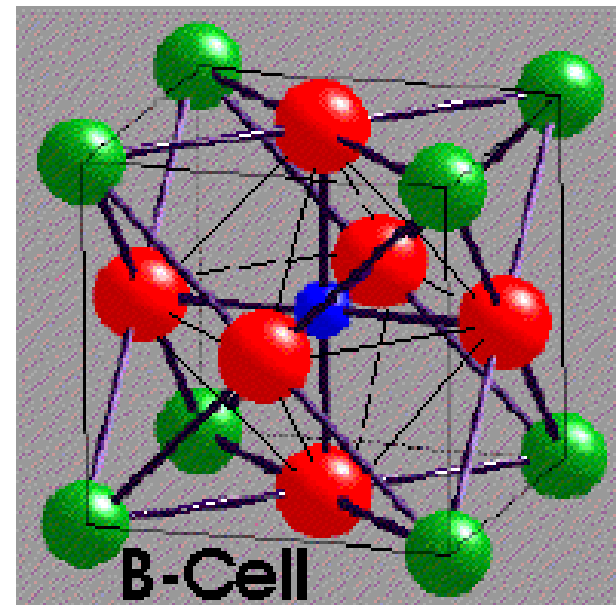


Perovskite CaTiO₃

● Ca ● Ti ● O

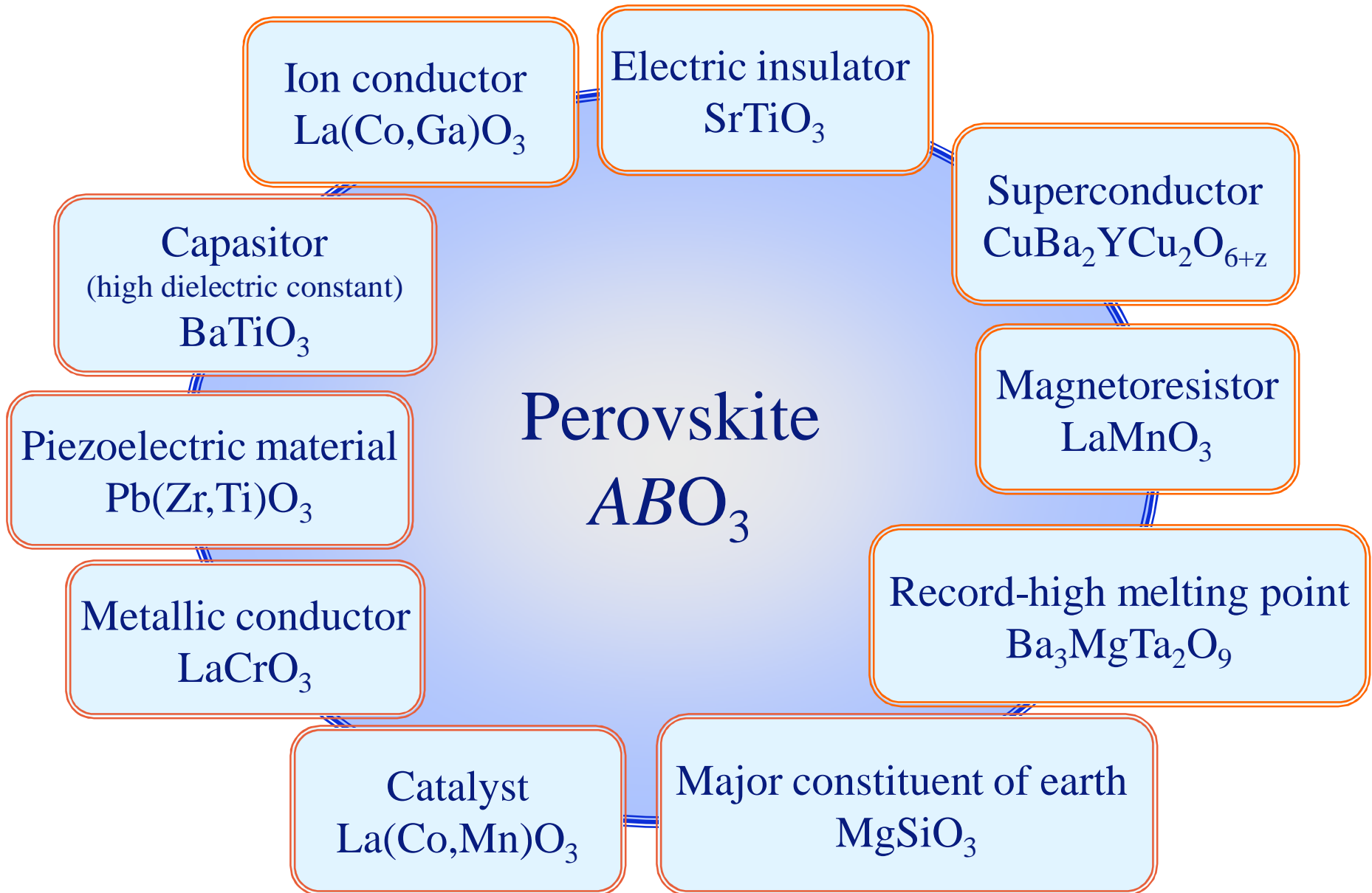


CaO₁₂ cuboctahedra



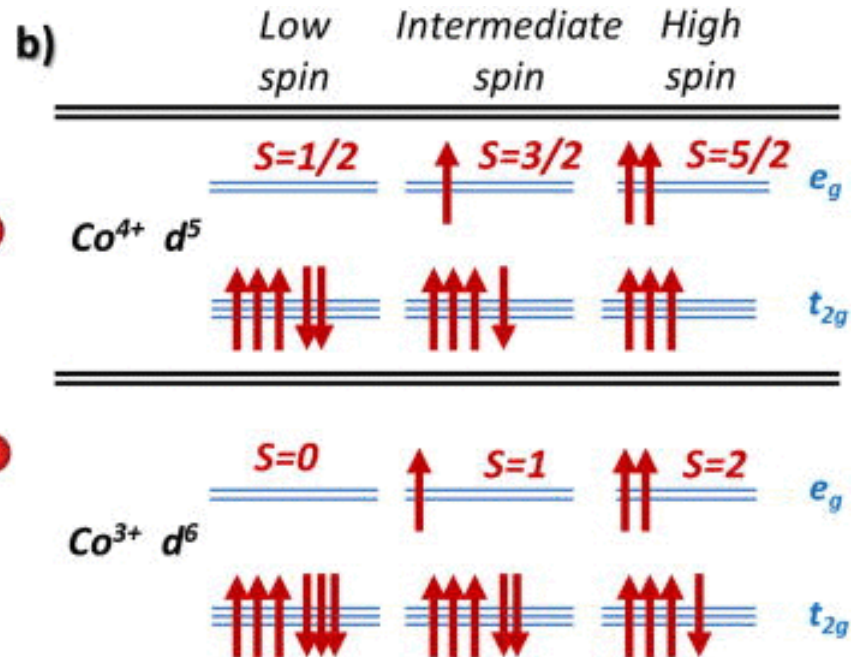
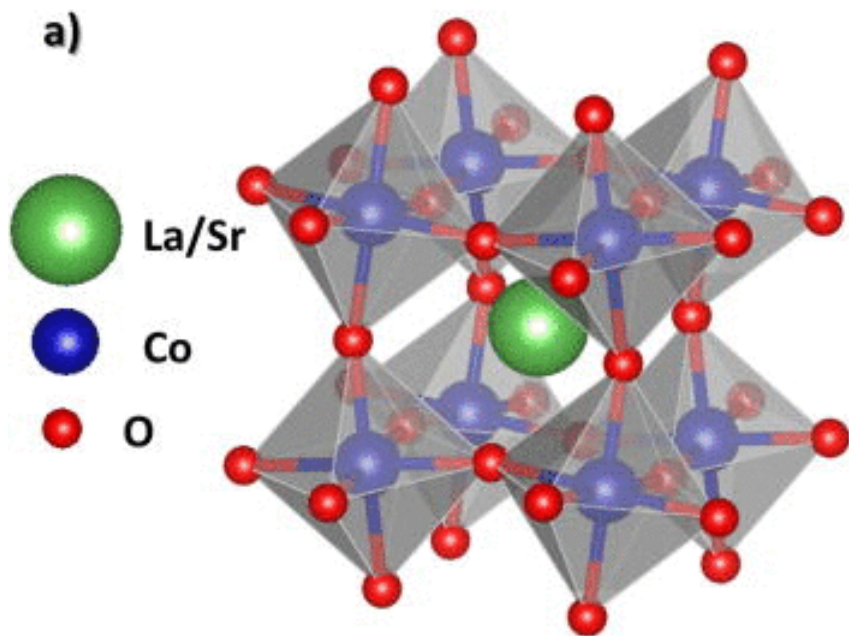
B-Cell

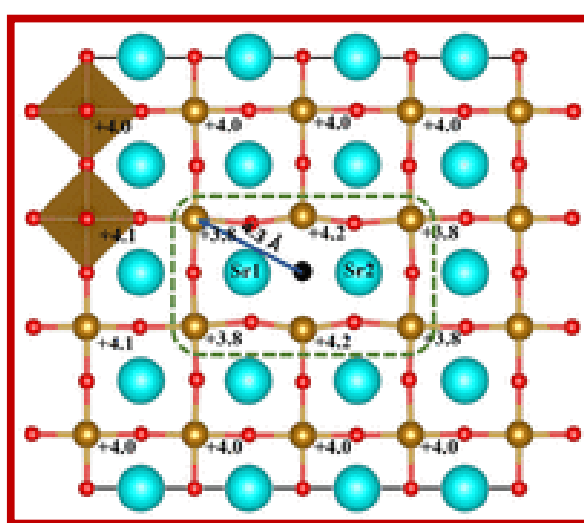
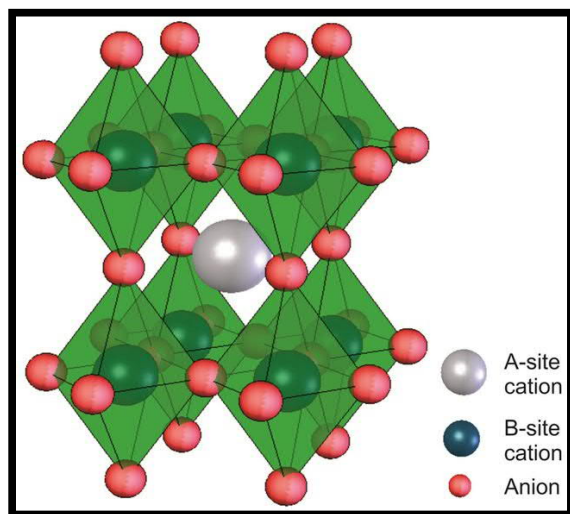
Perovskite – Multifunctional structure



ALIOVALENT SUBSTITUTIONS: Perovskite ($\text{La}^{3+}, \text{Sr}^{2+}$) CoO_3

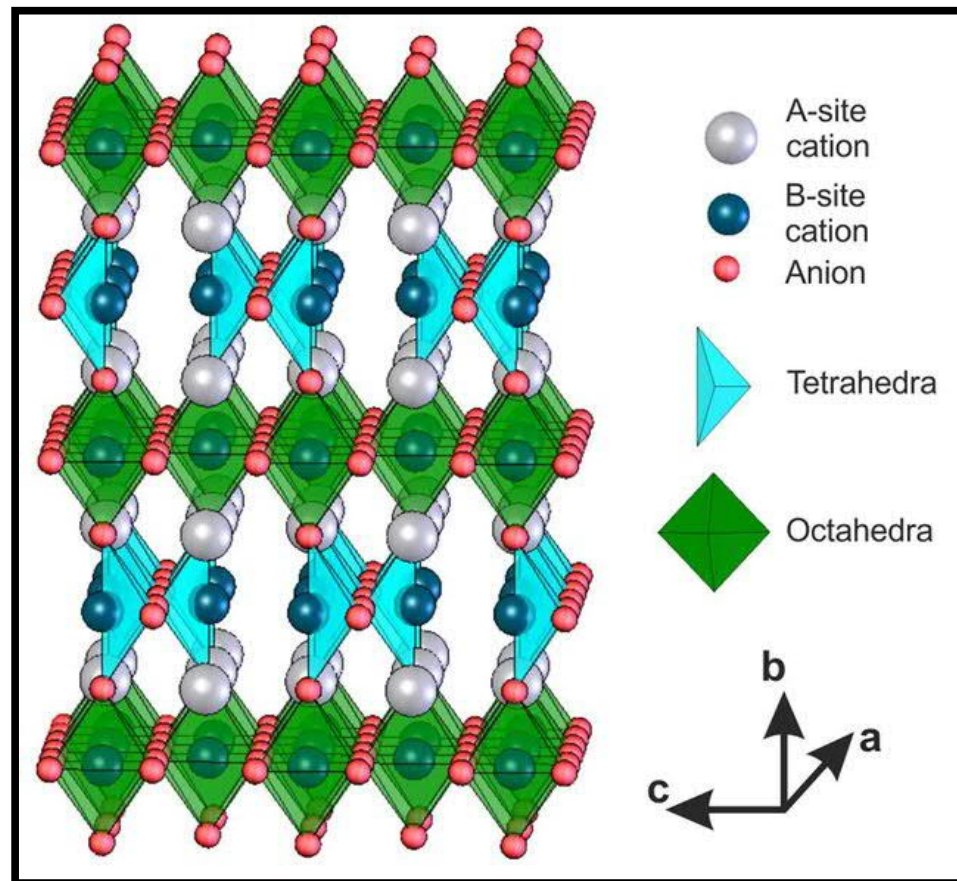
- Effect on Co valence ?
- Typical substitution levels ?
- What else may happen ?

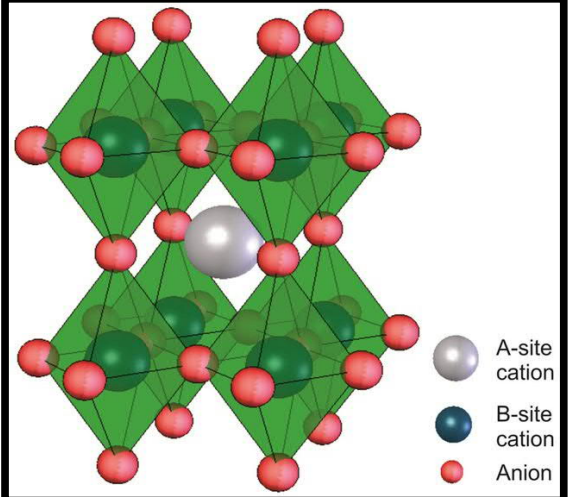




OXYGEN NONSTOICHIOMETRY: (La³⁺, Sr²⁺)CoO_{3-δ}

- Oxygen vacancies
- Random or Ordered
- Balance:
redox versus vacancies



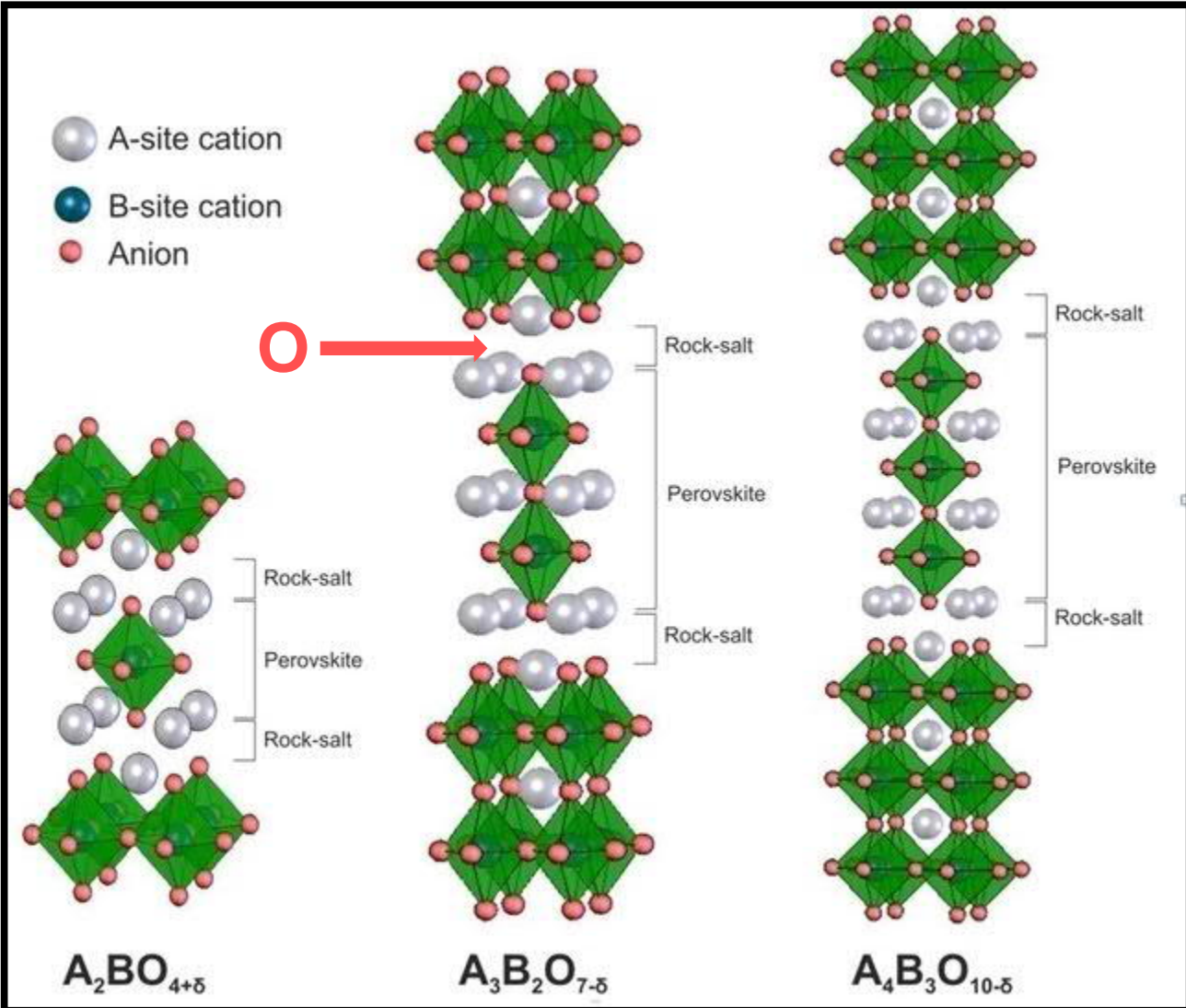


Perovskite ABO_3

- No space for interstitial oxygen

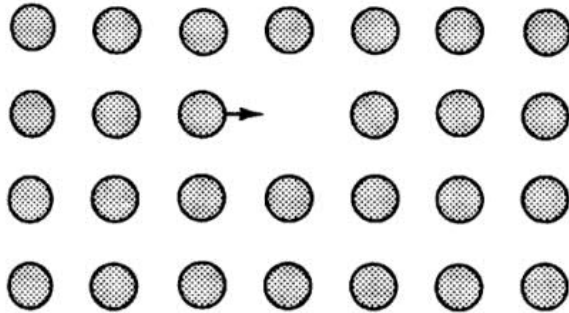
Ruddlesden-Popper $A_{n+1}B_nO_{1+3n}$

- Enough space for interstitial oxygen

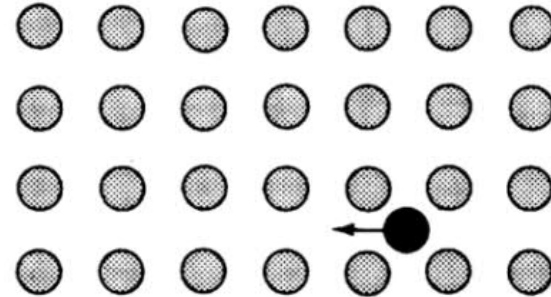


IONIC CONDUCTIVITY

- Mobile Vacancies or Interstitials



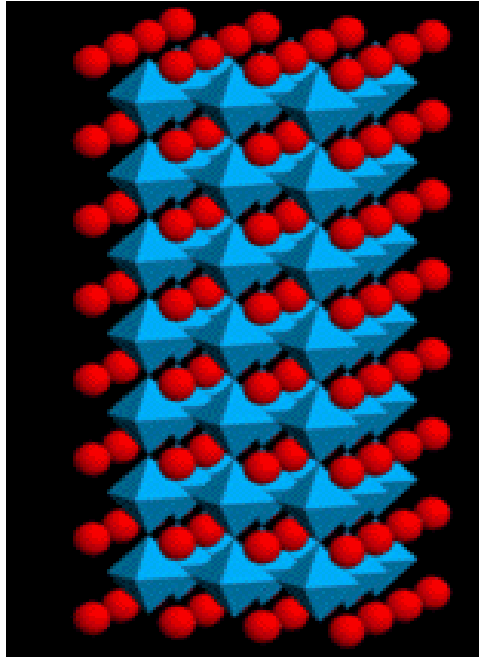
mobile vacancy



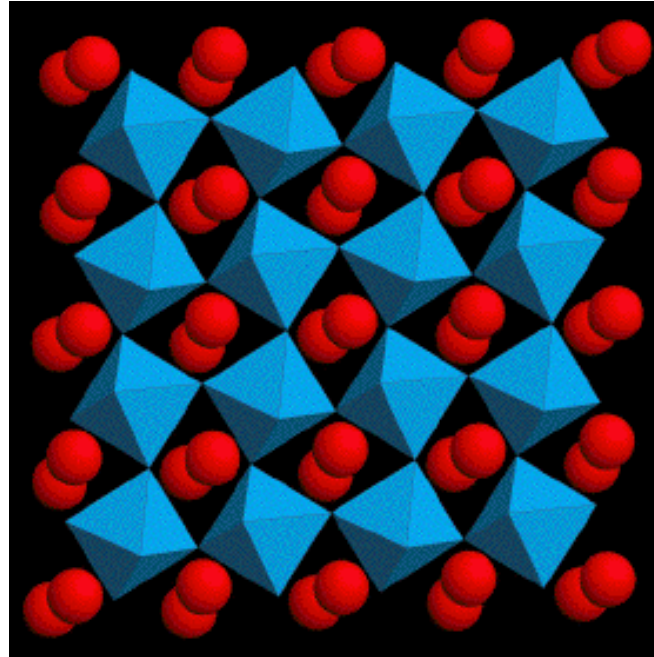
mobile interstitial

	Material	Conductivity (S m ⁻¹)
Ionic conductors	Ionic crystals	$< 10^{-16} - 10^{-2}$
	Solid Electrolytes	$10^{-1}-10^3$
	Liquid electrolytes	$10^{-1}-10^3$
Electronic conductors	Metals	10^3-10^7
	Semiconductors	$10^{-3}-10^4$
	Insulators	$< 10^{-10}$

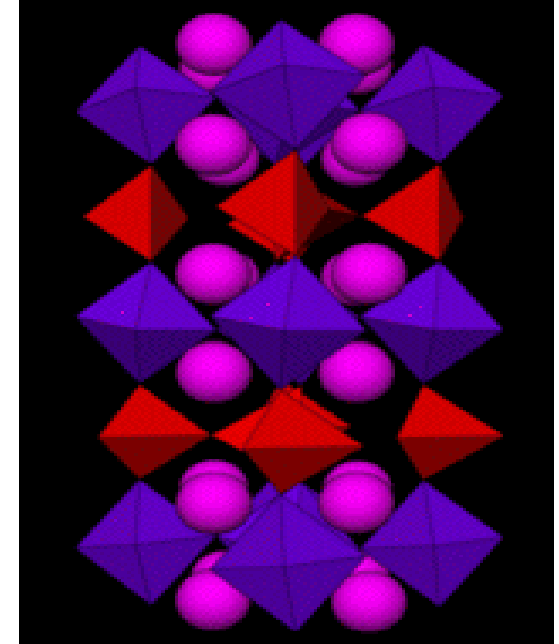
Distortions and Imperfections in Perovskite Structure: - often the source of the desired properties



IDEAL



**Changes in
atomic positions**

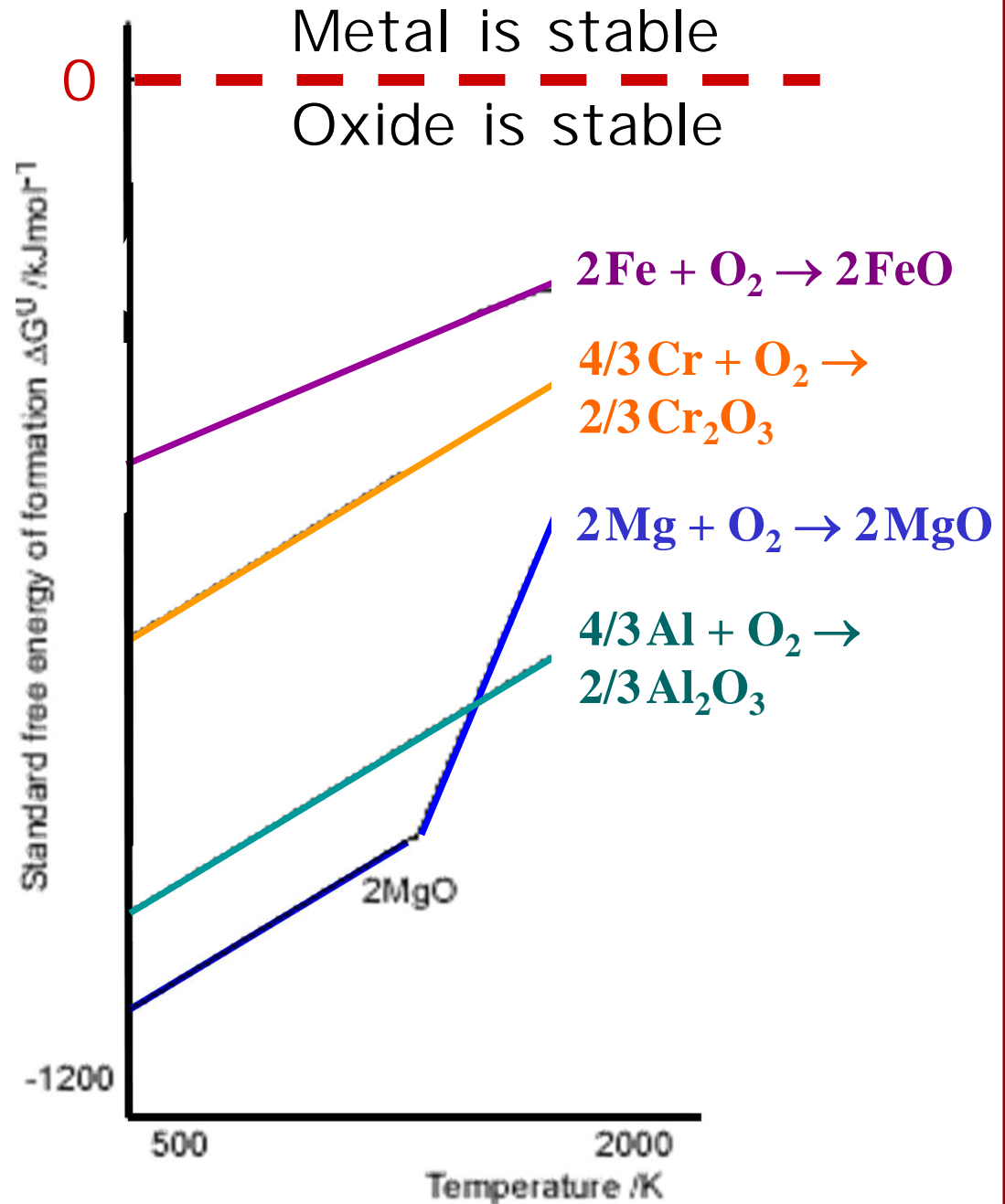
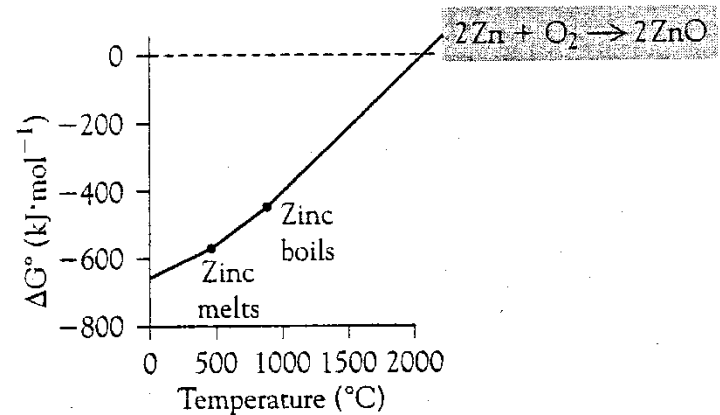


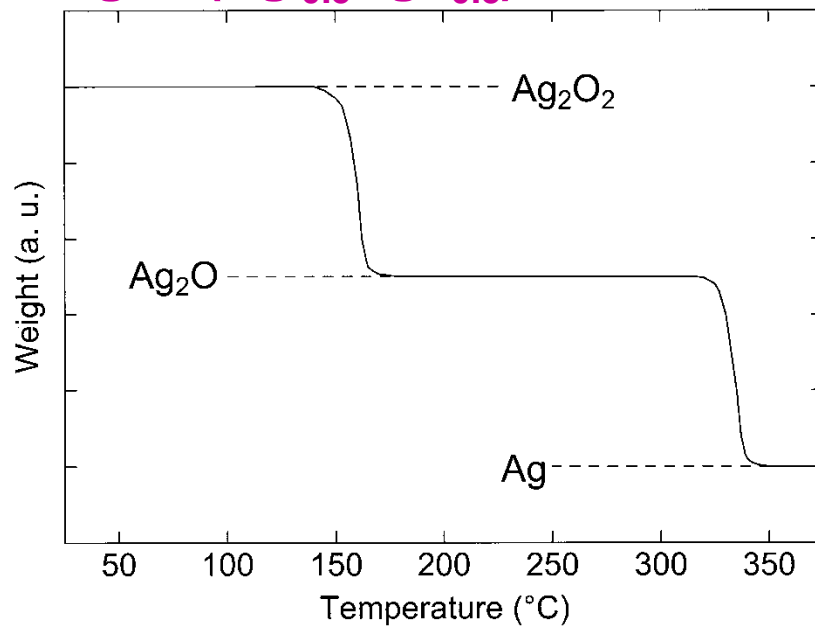
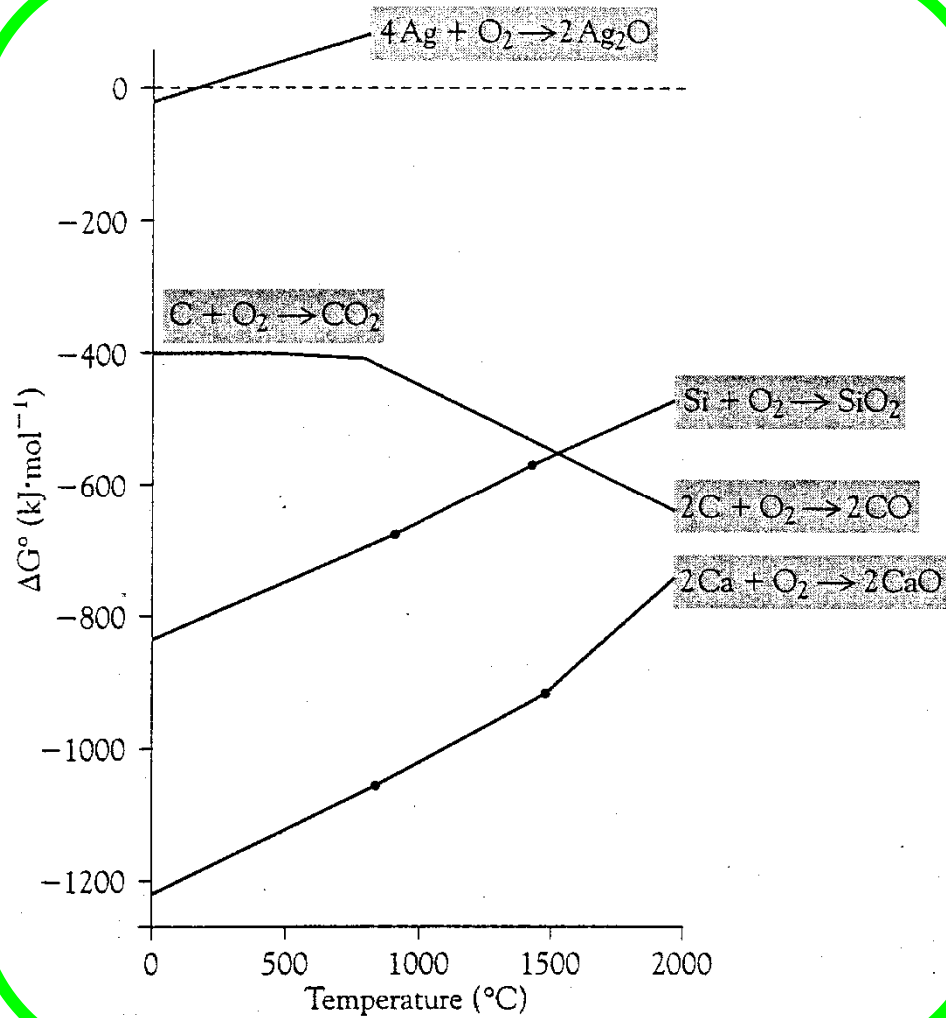
**Oxygen
deficiency**

Let's talk more about oxygen (non)stoichiometry →

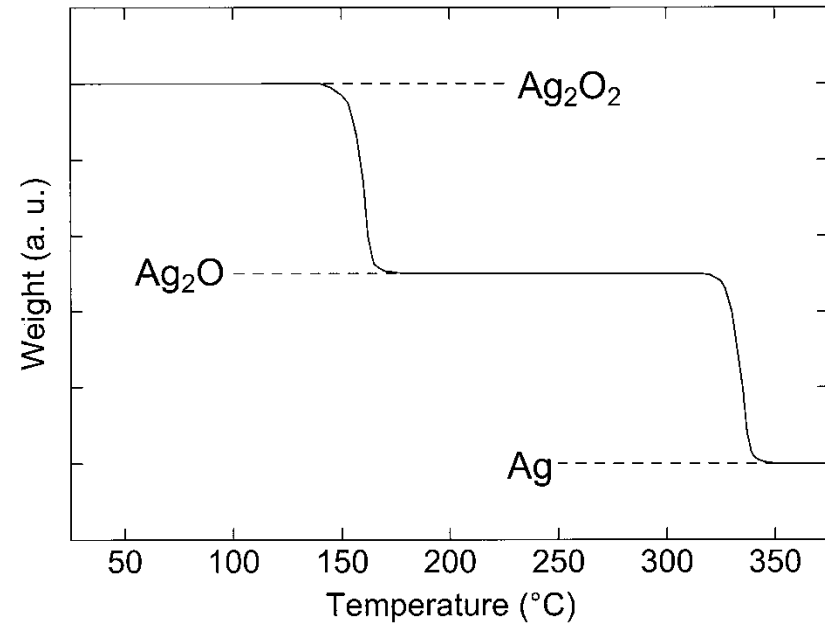
Ellingham diagram

- (Gibb's) free energy of formation versus temperature for metal oxides
- Temperature at which a metal oxide is spontaneously reduced to a metal

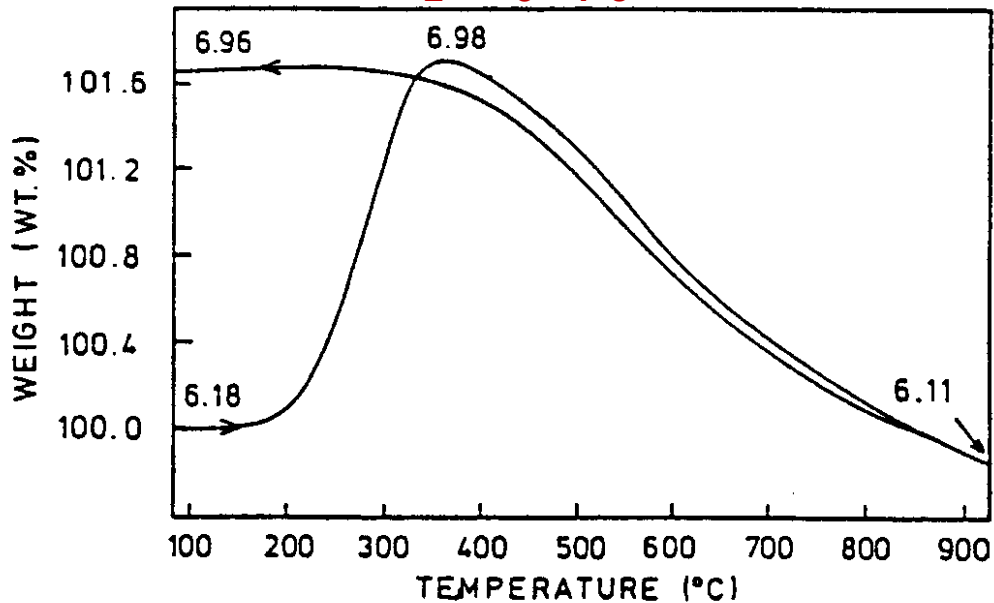




TG of AgO in air

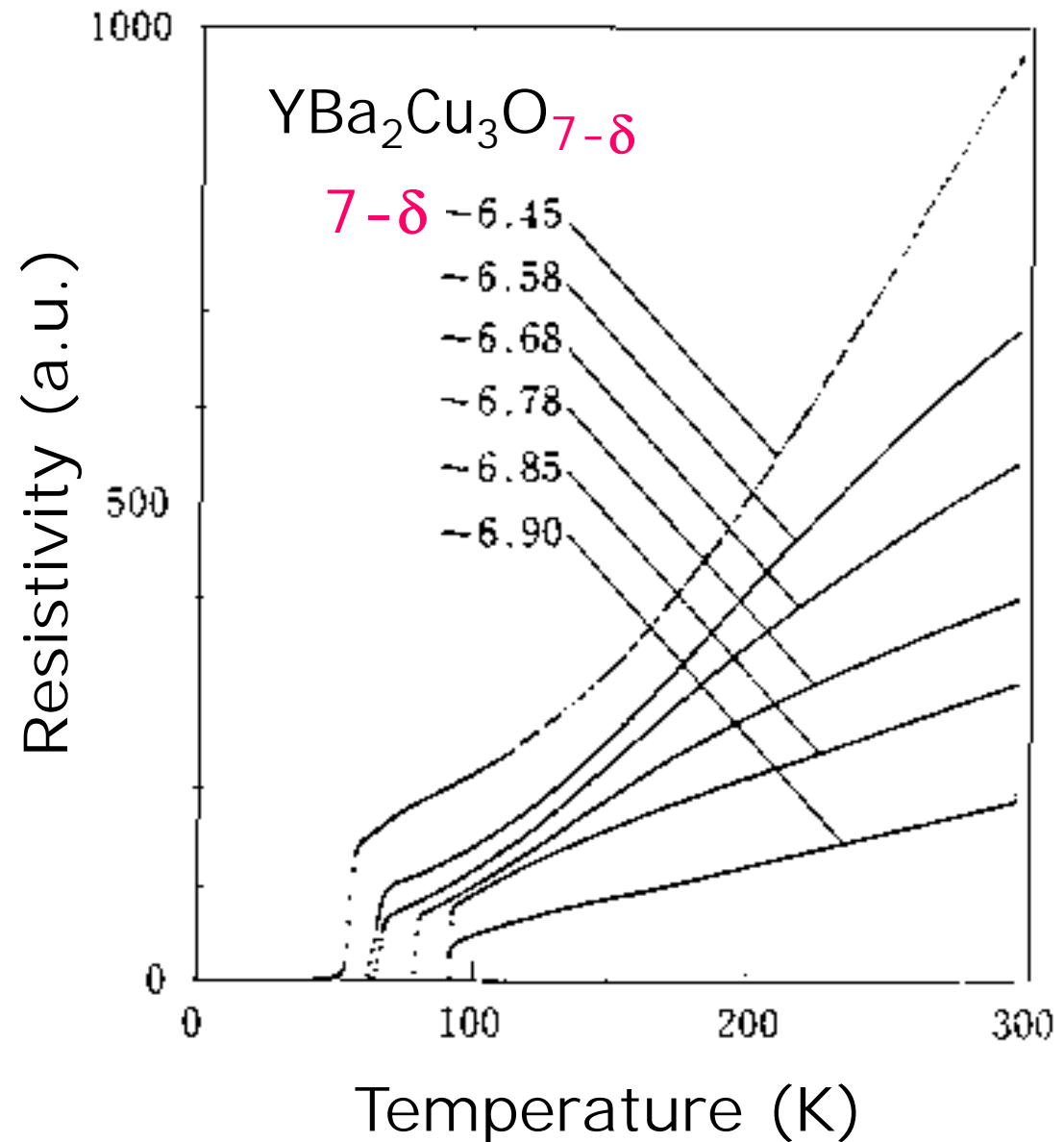
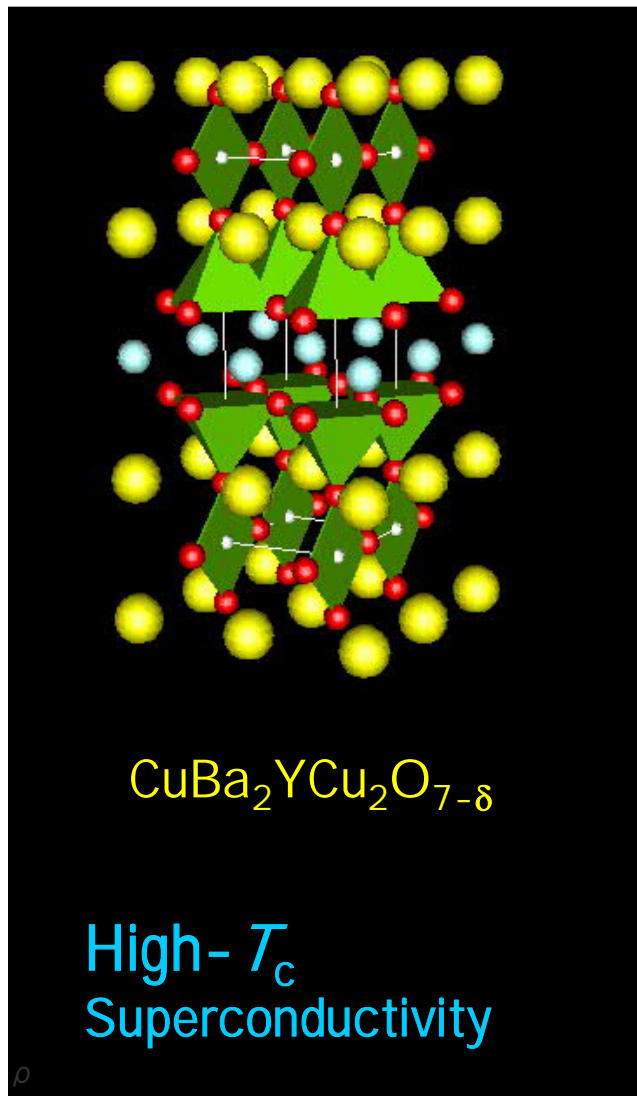


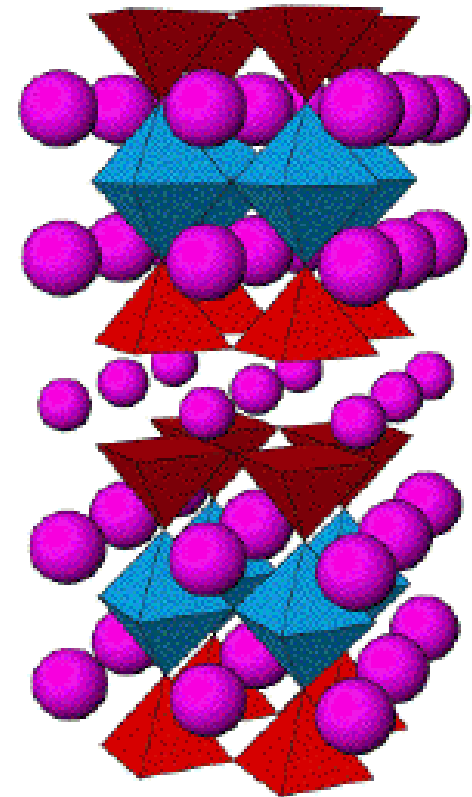
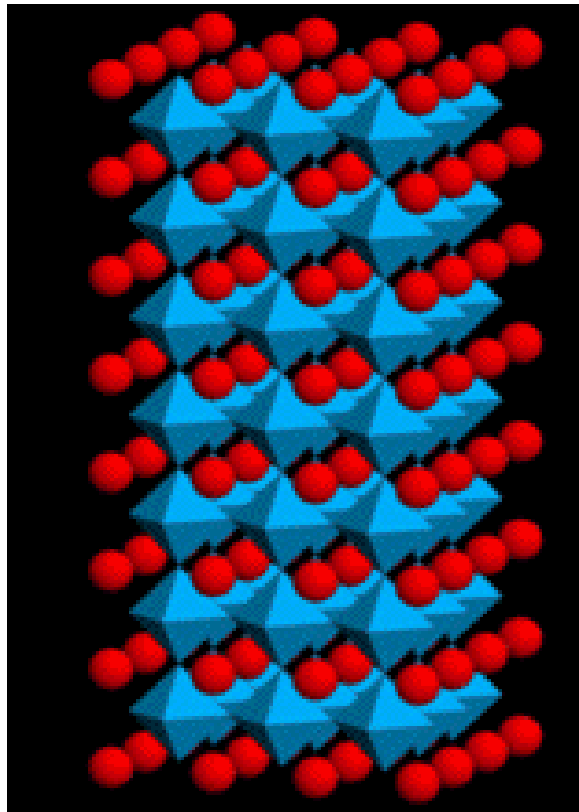
TG of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ in air

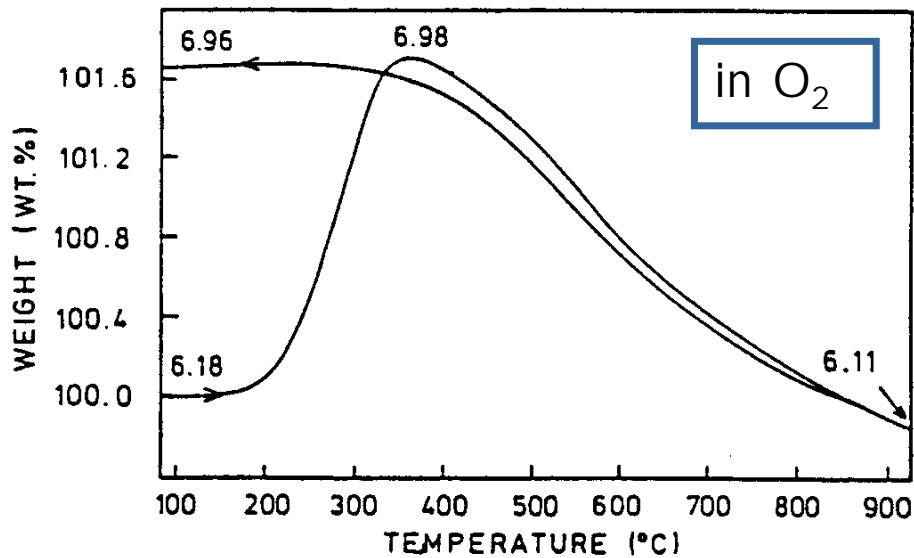
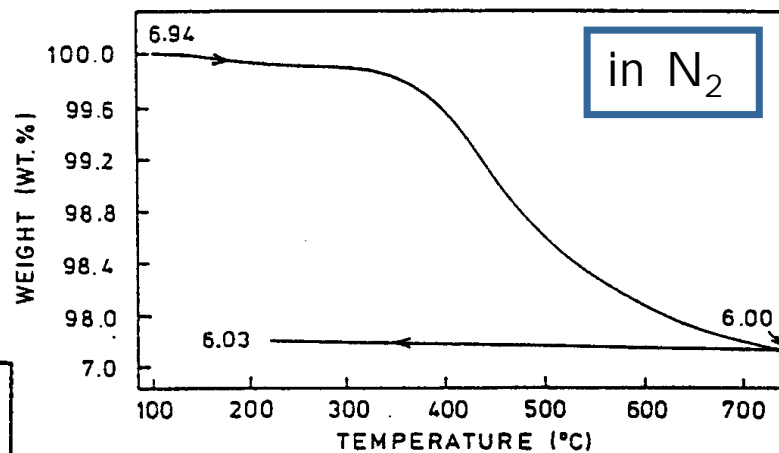
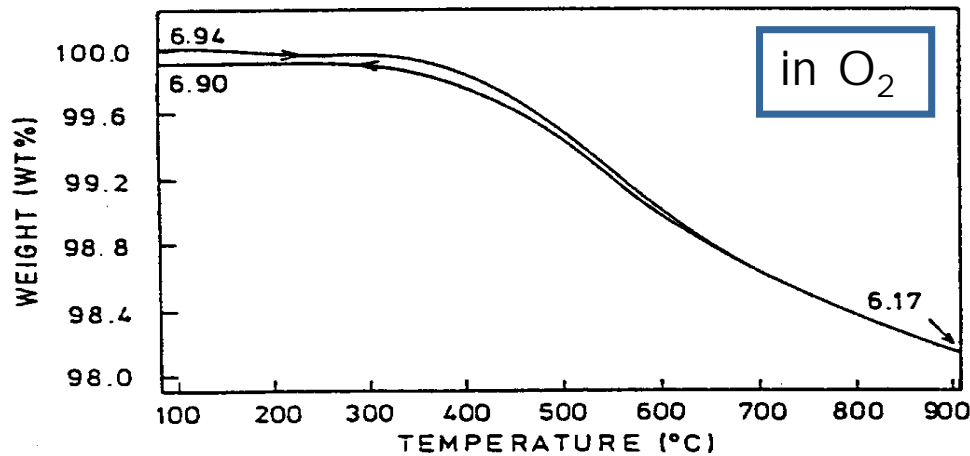
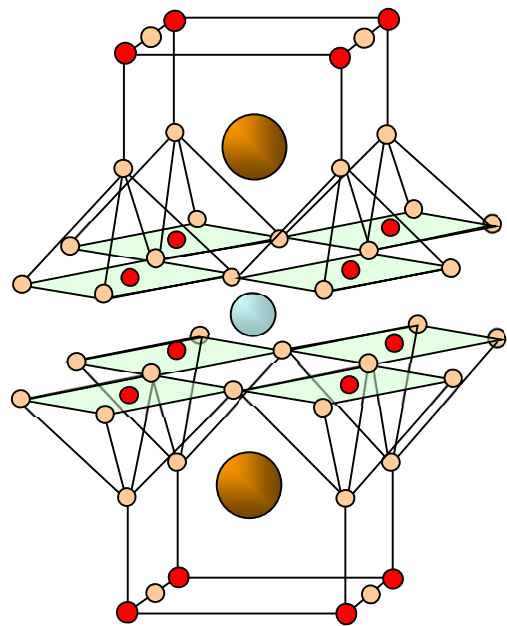


**Gradual oxygen loss
→ Mixed-valent Cu**

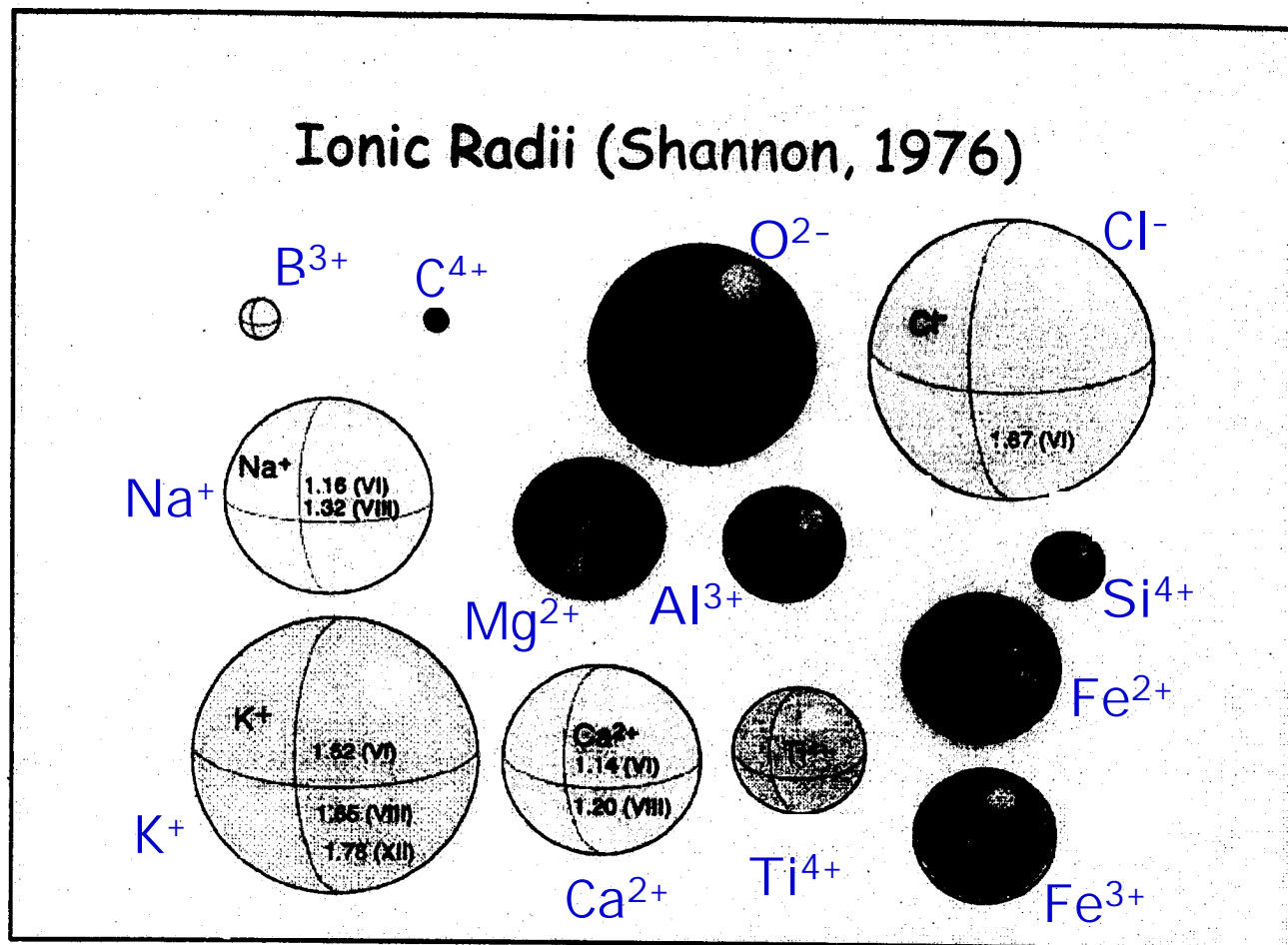
SUPERCONDUCTIVITY depends on OXYGEN CONTENT

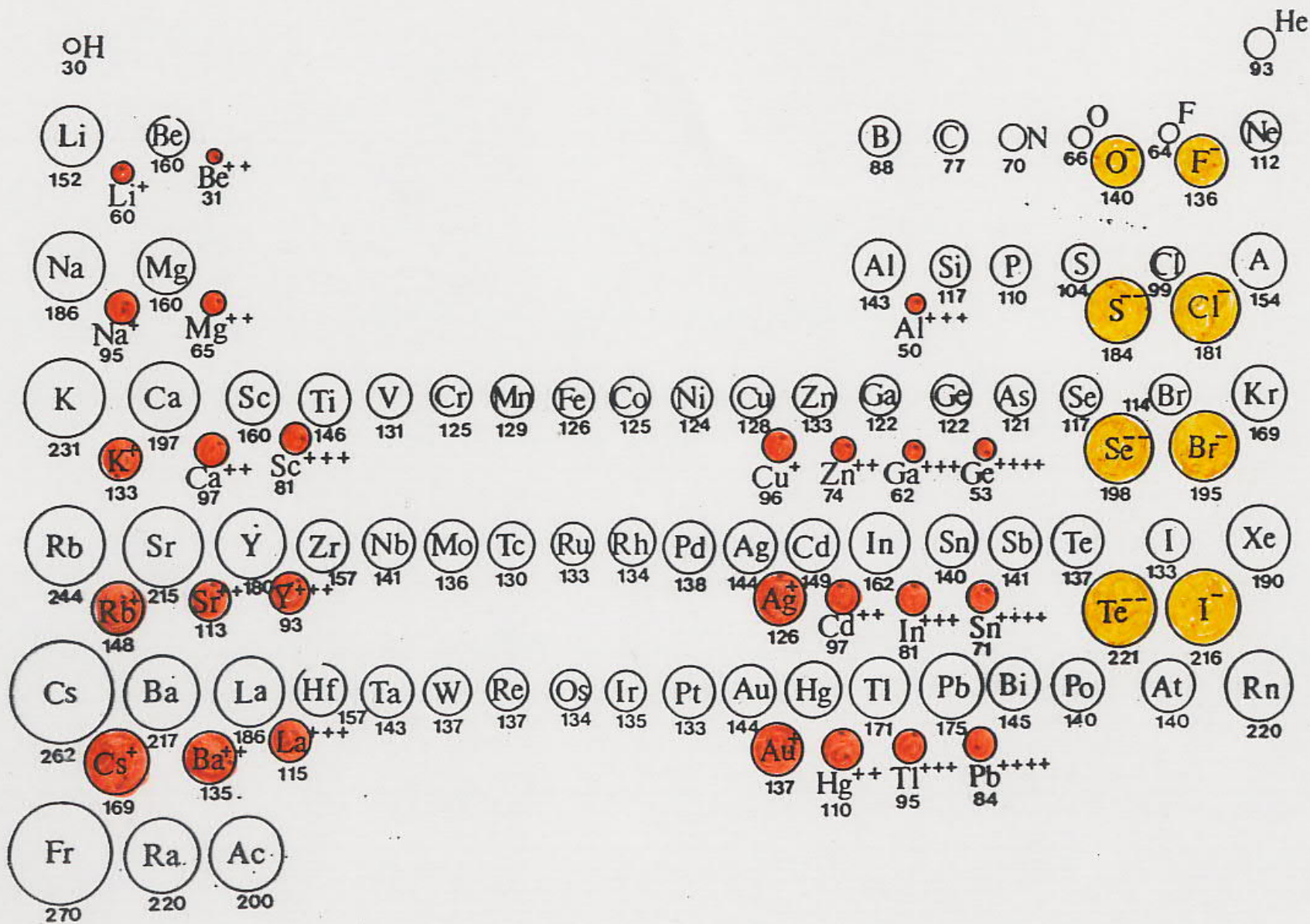




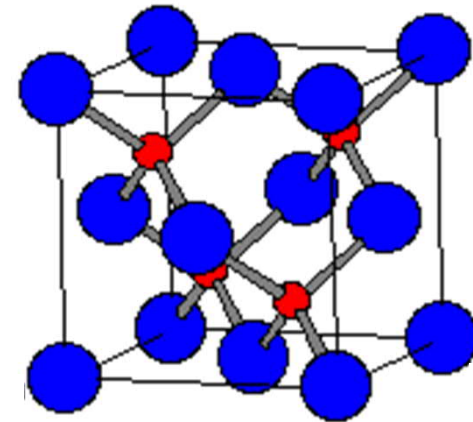


MATCHING of IONIC RADIUS values important for the formation of the CRYSTAL STRUCTURE → NEW-MATERIAL DESIGN TOOL

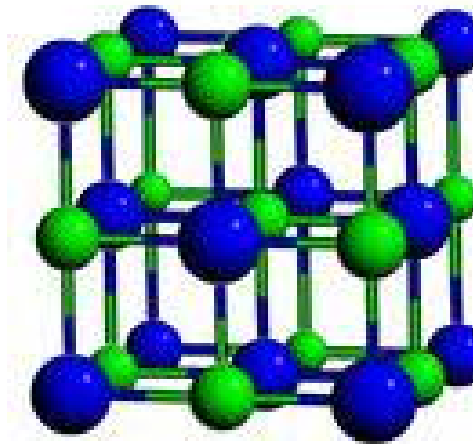




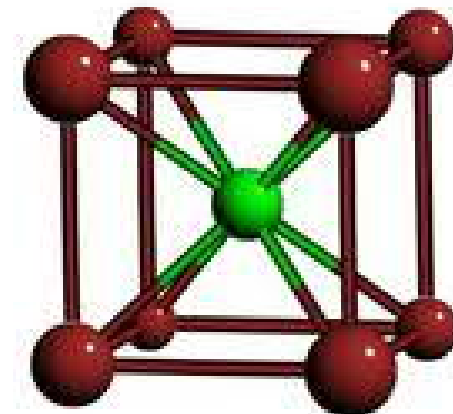
Binary AB compounds



ZnS



NaCl



CsCl

Pauling's Rule

$$r_C/r_A < 0.155$$

$$0.155 < r_C/r_A < 0.225$$

$$0.225 < r_C/r_A < 0.414$$

$$0.414 < r_C/r_A < 0.732$$

$$0.732 < r_C/r_A < 1.00$$

$$r_C/r_A > 1.00$$

$$\text{CN} = 2$$

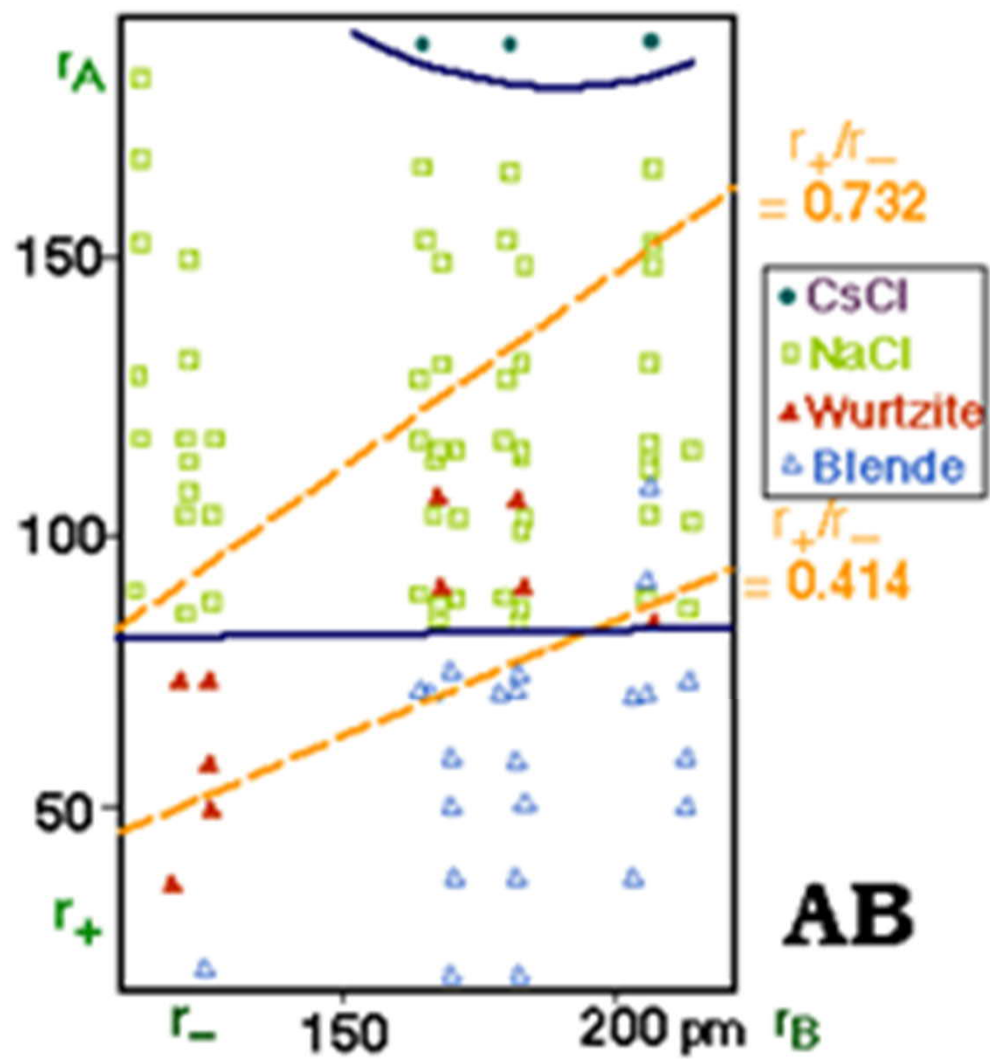
$$\text{CN} = 3$$

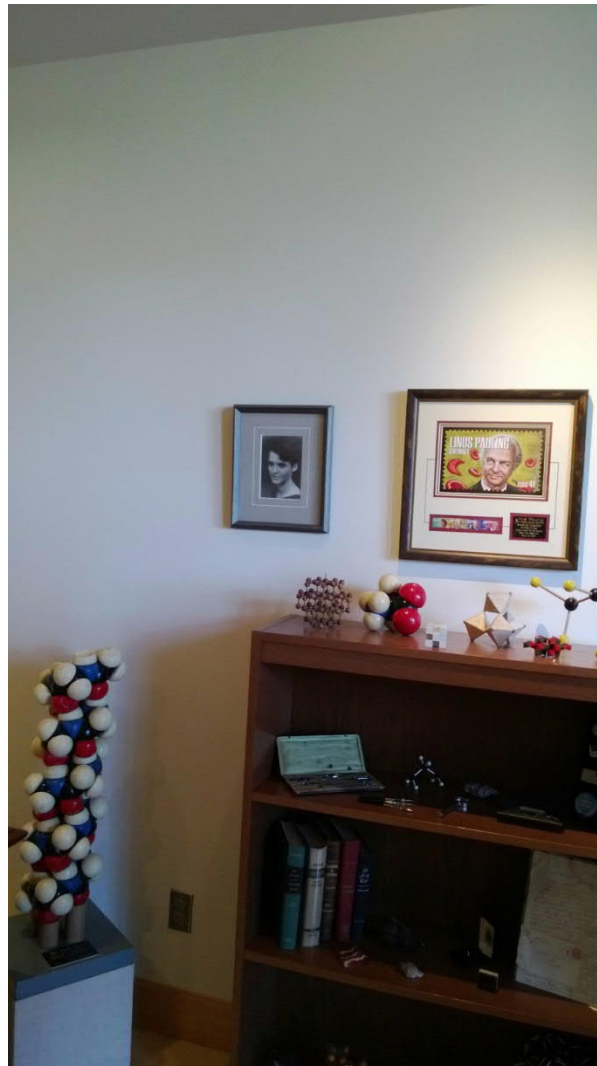
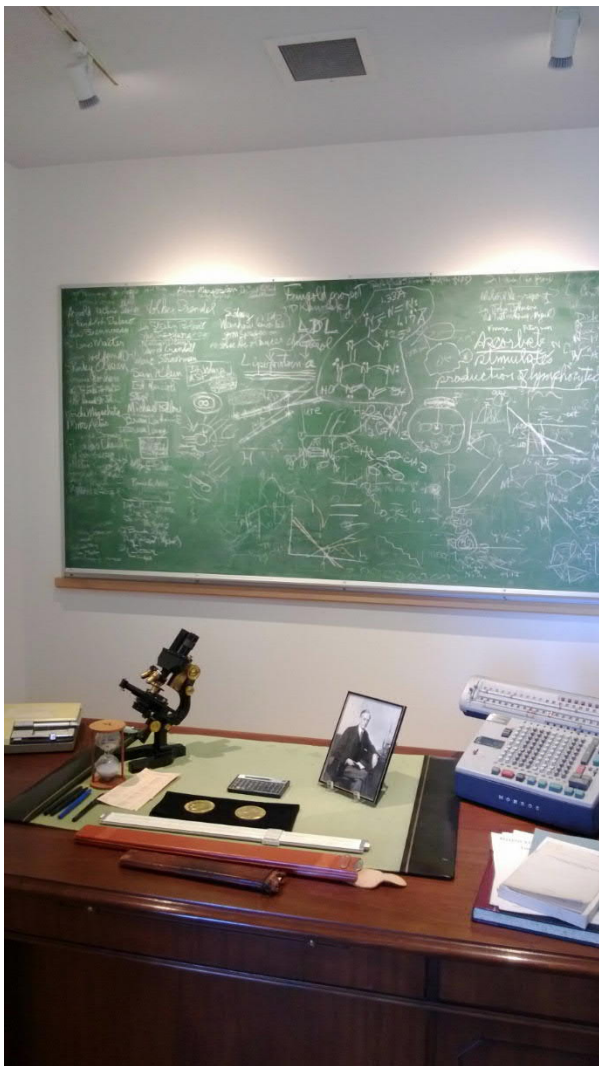
$$\text{CN} = 4$$

$$\text{CN} = 6$$

$$\text{CN} = 8$$

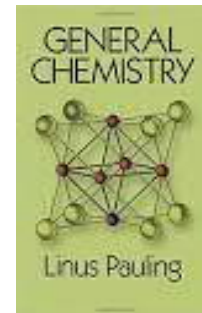
$$\text{CN} = 12$$



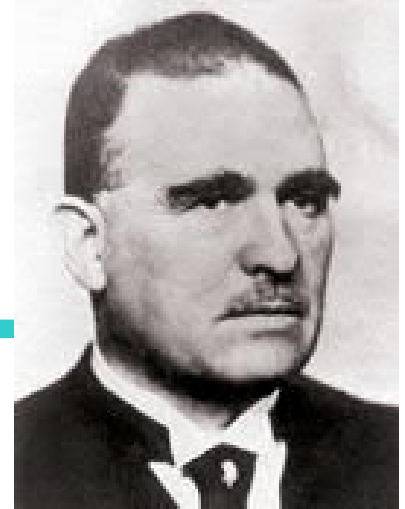


Linus Pauling (1901–1994)

- American chemist, quantum chemist, biochemist and peace activist
- Graduated from Oregon State University
- 1939: “The Nature of the Chemical Bond”
- 1954: Nobel Prize in Chemistry
- 1962: Nobel Peace Prize



**Victor Moritz Goldschmidt
(1888-1947)**



TOLERANCE FACTOR (t)

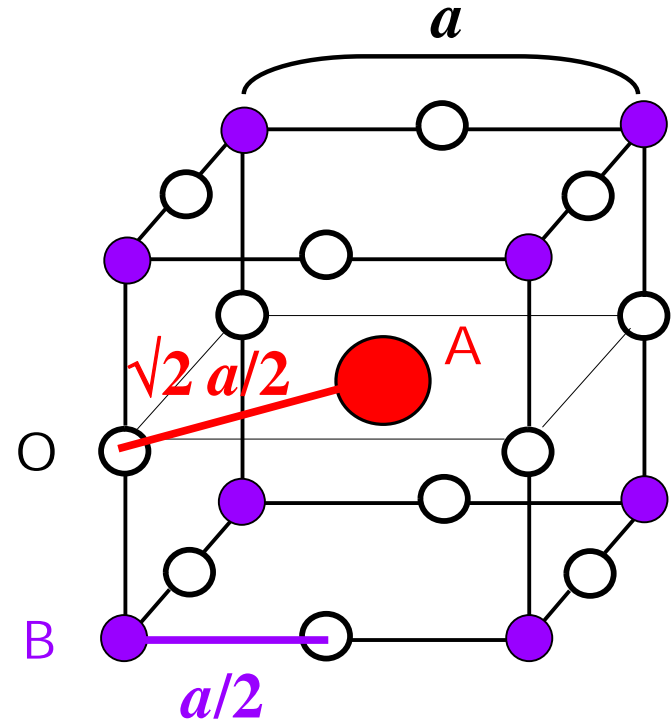
- 1926 Goldschmidt

**V.M. Goldschmidt , “Geochemische Verteilungsgesetze der Elemente”,
Skrifter Norske Videnskaps-Akad, Oslo, I. Mat-Naturr. K1 (1926)**

- t : measure for the degree of mismatch between two different atomic layers
- Calculated from preferred bond lengths
- Preferred bond lengths are estimated from ionic radii
R.D. Shannon, Acta Cryst. A 32, 751 (1976)

Tolerance factor for ABO_3 perovskite

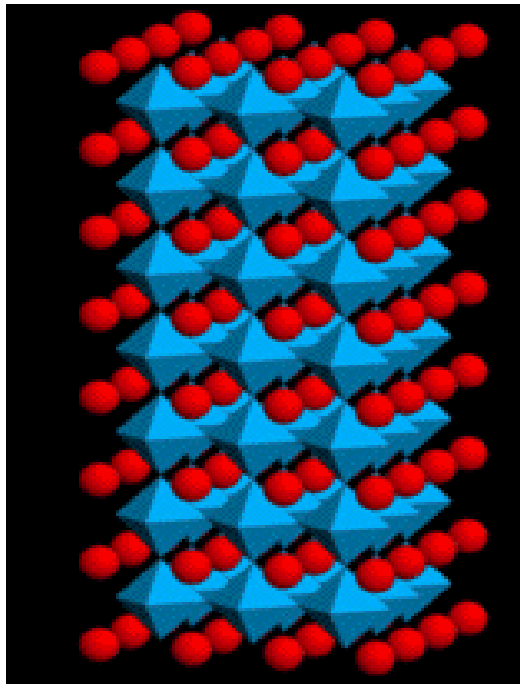
$$t = \frac{(r_A + r_O)}{\sqrt{2} (r_B + r_O)}$$



- $t = 1$: ideal matching (0.80 < t < 1.05 possible)
- $t < 1$: A is too small \rightarrow change in oxygen position
- $t > 1$: B is too small \rightarrow B reduced \rightarrow oxygen vacancies

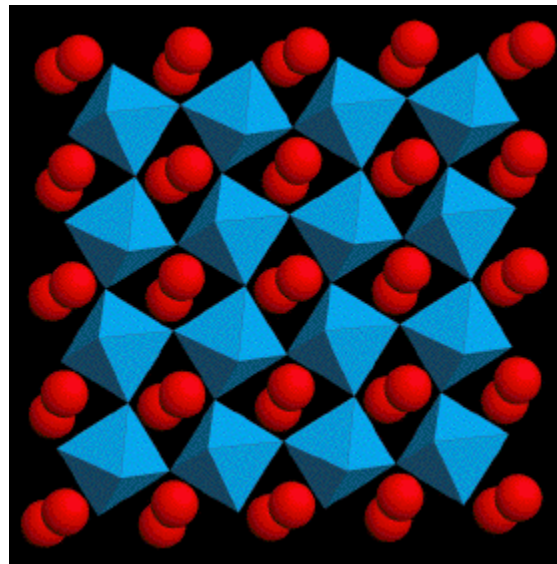
$$t = \frac{(r_A + r_O)}{\sqrt{2} (r_B + r_O)}$$

$t = 1$



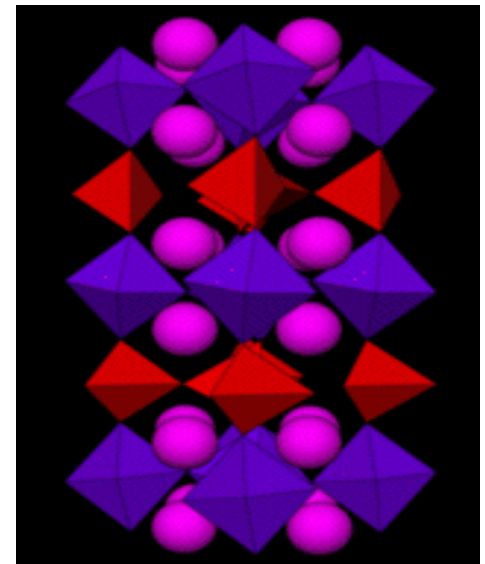
Ideal perovskite

$t < 1$

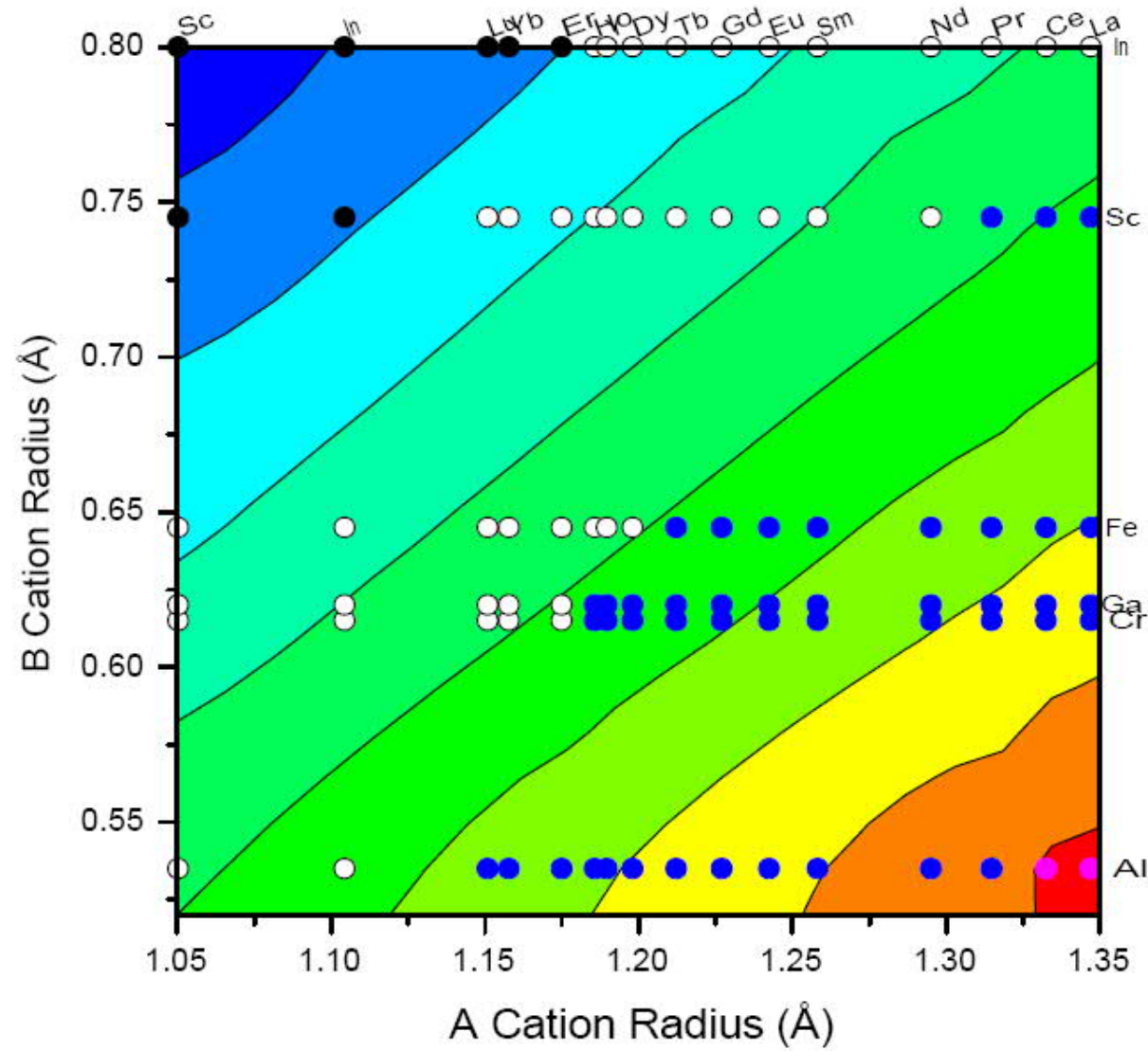
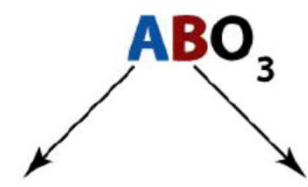


Changes in
atomic positions

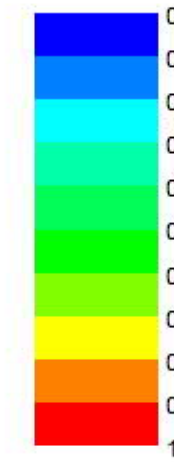
$t > 1$



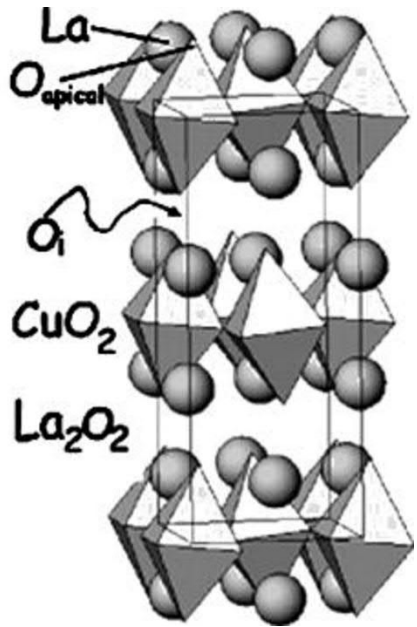
Oxygen deficiency



Tolerance Factor

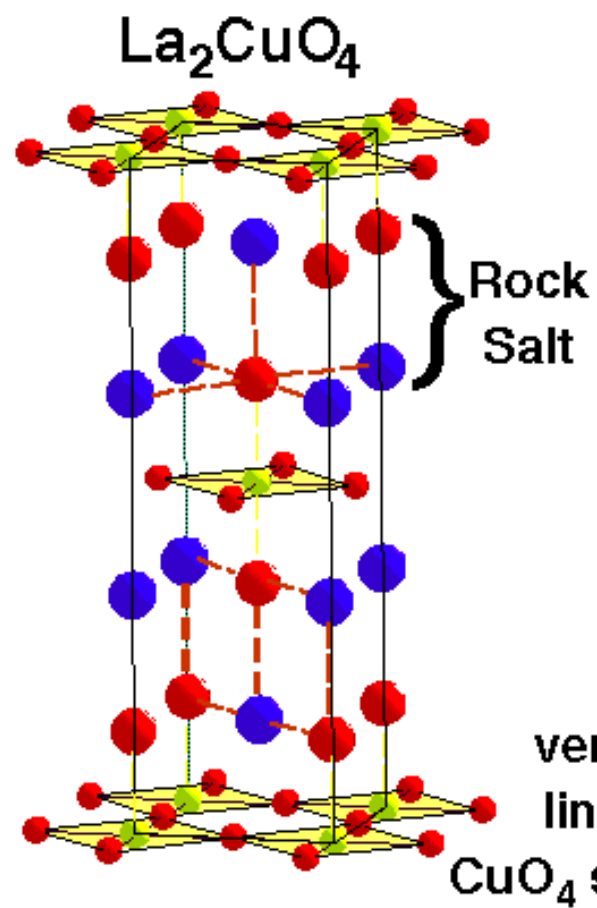


- Pnma Perovskite orthorhombic
- P6₃cm Perovskite hexagonal
- R-3c Perovskite cubic
- Ia3 Bixbyite



EFFECT OF COORDINATION SPHERE

p-type doping



n-type doping

